

## CCFC3007PT Microcontroller Data Sheet

- Three main CPUs, single issue, 32-bit CPU core complexes (C3007), one of which is a dedicated lockstep core.
  - Power Architecture<sup>®</sup> embedded specification compliance
  - Instruction set enhancement allowing variable length encoding (VLE), encoding a mix of 16-bit and 32-bit instructions, for code size footprint reduction
  - Single-precision floating point operations
  - 16 KB Local instruction RAM and 64 KB local data RAM
  - 16 KB I-Cache and 4 KB D-Cache
- I/O Processor, dual issue, 32-bit CPU core complex (C2004), with
  - Power Architecture embedded specification compliance
  - Instruction set enhancement allowing variable length encoding (VLE), encoding a mix of 16-bit and 32-bit instructions, for code size footprint reduction
  - Single-precision floating point operations
  - Lightweight Signal Processing Auxiliary Processing Unit (LSP APU) instruction support for digital signal processing (DSP)
  - 16 KB Local instruction RAM and 64 KB local data RAM
  - 8 KB I-Cache
- 13568 KB on-chip flash
  - Include 13056Kbytes Code flash supports read during program and erase operations, and 512Kbytes allowing EEPROM emulation
- 1.5 MB System RAM
- Multichannel direct memory access controllers (eDMA): 2 x 64 channels per eDMA (128 channels total)
- Triple Interrupt controller (INTC)
- Dual phase-locked loops with stable clock domain for peripherals and FM modulation domain for computational shell
- Dual crossbar switch architecture for concurrent access to peripherals, flash, or RAM from multiple bus masters with end-to-end ECC
- Real Time Clock / Autonomous Periodic Interrupt (RTC/API)
- Hardware Security Module (HSM) to provide robust integrity checking of flash memory
- System Integration Unit Lite (SIUL)
- Boot Assist Module (BAM) supports factory programming using serial bootload through LINFlexD\_0 or MCAN1
- GTM104 — generic timer module
- Enhanced analog-to-digital converter system with
  - Ten separate 12-bit Enhanced Queued analog converters
  - Eight separate 16-bit Sigma-Delta analog converters
- Eight deserial serial peripheral interface (DSPI) modules
- Two Peripheral Sensor Interface (PSI5) controllers support 5 channels
- Two I2C controllers support master and slave
- Two SENT Receivers support 15 channels
- Two CSENT with 15 channels which support sent frame receiver and transmit
- Two eMIOS controller support 32 channels
- Three eTPU co-processor support 96 channels
- Sixteen LINFlexD support LIN Master/Slave and UART communication interface
- Twelve modular controller area network (MCAN) modules and three time-triggered controller area networks (M-TTCAN)
- Two CAST CANFD Controller which support controller area network and time-triggered controller area networks
- One DWC\_ether\_qos Ethernet Controller (MAC) and TSN feature :
  - supports 10 and 100 Mbps Ethernet/IEEE 802.3 networks
  - IEEE 802.1Qbv-2015, Enhancements to Scheduling Traffic
  - IEEE802.1Qbu/802.3br, Frame preemption and Interspersing Express Traffic
- Two I2S(SAI)
- Two QSPI which support 4 bit width transmit
- Nexus development interface (NDI) per IEEE-ISTO 5001-2003 standard, with some support for 2010 standard
- Device and board test support per Joint Test Action Group (JTAG)(IEEE 1149.1)
- Self-test capability

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# 1 Introduction

## 1.1 Document overview

This document provides electrical specifications, pin assignments, and package diagrams for the CCFC3007PT series of microcontroller units (MCUs). For functional characteristics, see the *CCFC3007PT Microcontroller Reference Manual*.

## 1.2 Description

This family of MCUs is targeted at automotive powertrain controller and chassis control applications from single cylinder motorcycles at the very bottom end; through 4 to 8 cylinder gasoline and diesel engines; transmission control; steering and breaking applications; to high end hybrid and advanced combustion systems at the top end.

Many of the applications are considered to be functionally safe and the family is designed to achieve ISO26262 ASIL-D compliance.

| Version                       | CCFC3007BCT64L9          | CCFC3007BCT192L9         | CCFC3007BCT192B4         | CCFC3007PTT192B2         | CCFC3007PTT192B4         | CCFC3007PTT192B6         |
|-------------------------------|--------------------------|--------------------------|--------------------------|--------------------------|--------------------------|--------------------------|
| Type                          | 32 bit multiprocessor    | 32 bit multiprocessor    | 32 bit multiprocessor    | 32 bit multiprocessor    | 32 bit multiprocessor    | 32 bit multiprocessor    |
| CPU                           | 2*C3007+C3007 (lockstep) | 2*C3007+C3007 (lockstep) | 2*C3007+C3007 (lockstep) | 2*C3007+C3007 (lockstep) | 2*C3007+C3007 (lockstep) | 2*C3007+C3007 (lockstep) |
| Frequence                     | 300MHZ                   | 300MHZ                   | 300MHZ                   | 300MHZ                   | 300MHZ                   | 300MHZ                   |
| RAM                           | 640K                     | 640K                     | 640K                     | 1.5M                     | 1.5M                     | 1.5M                     |
| C-flash                       | 4M                       | 12M                      | 12M                      | 12M                      | 12M                      | 12M                      |
| D-flash                       | 512K                     | 512K                     | 512K                     | 512K                     | 512K                     | 512K                     |
| Package                       | LQFP216                  | LQFP216                  | BGA416                   | BGA292                   | BGA416                   | BGA516                   |
| Operating temperature (°C)    | -40°C ~ 125°C (TA)       | -40°C ~ 125°C (TA)       | -40°C ~ 125°C (TA)       | -40°C ~ 125°C (TA)       | -40°C ~ 125°C (TA)       | -40°C ~ 125°C (TA)       |
| Operating voltage (V)         | 3.3/5                    | 3.3/5                    | 3.3/5                    | 3.3/5                    | 3.3/5                    | 3.3/5                    |
| I/O number                    | 153                      | 153                      | 333                      | 187                      | 333                      | 378                      |
| CAN(FD) (ch)                  | 10 (CanFD)               | 10 (CanFD)               | 12 (CanFD)               | 12 (CanFD)               | 12 (CanFD)               | 14 (CanFD)               |
| LIN (ch)                      | 11                       | 11                       | 16                       | 16                       | 16                       | 16                       |
| SPI (ch)                      | 6                        | 6                        | 8                        | 8                        | 8                        | 8                        |
| QSPI (ch)                     | 2                        | 2                        | 2                        | 2                        | 2                        | 2                        |
| I2C (ch)                      | 2                        | 2                        | 2                        | 2                        | 2                        | 2                        |
| ETHER                         | 1                        | 1                        | 1                        | 1                        | 1                        | 1                        |
| SENT                          | 13                       | 13                       | 15                       | 15                       | 15                       | 15                       |
| PSI5                          | 3                        | 3                        | 5                        | 4                        | 5                        | 5                        |
| AD (ch)                       | 36                       | 36                       | 70                       | 45                       | 70                       | 84                       |
| DMA                           | 128                      | 128                      | 128                      | 128                      | 128                      | 128                      |
| eTPU                          | -                        | -                        | -                        | 96                       | 96                       | 96                       |
| GTM                           | Y                        | Y                        | Y                        | Y                        | Y                        | Y                        |
| eMIOS (ch)                    | 64                       | 64                       | 64                       | 64                       | 64                       | 64                       |
| HSM                           | Y                        | Y                        | Y                        | Y                        | Y                        | Y                        |
| Reliability Functional Safety | AEC-Q100 ASIL-B          | AEC-Q100 ASIL-B          | AEC-Q100 ASIL-B          | AEC-Q100 ASIL-D          | AEC-Q100 ASIL-D          | AEC-Q100 ASIL-D          |
| Replaceability                | MPC5775E/TC367           | MPC5775E/TC367           | MPC5775E/TC367           | MPC5777M/TC387           | MPC5777M/TC387           | MPC5777M/TC387           |
| Mass production time          | 2023Q2                   | 2023Q2                   | 2023Q2                   | 2023Q3                   | 2023Q3                   | 2023Q3                   |

## 1.3 Device feature

Table 1. CCFC3007PT feature

| Feature                  |                                 | CCFC3007PT                      |
|--------------------------|---------------------------------|---------------------------------|
| Process                  |                                 | TSMC 40 nm                      |
| Safety Goal              |                                 | ASIL-D                          |
| Main processor           | Core                            | C3007                           |
|                          | Number of main cores            | 2                               |
|                          | Number of checker cores         | 1                               |
|                          | Local RAM (per main core)       | 16 KB Instruction<br>64 KB Data |
|                          | Single precision floating point | Yes                             |
|                          | LSP                             | No                              |
|                          | VLE                             | Yes                             |
|                          | Cache                           | 16 KB Instruction<br>4 KB Data  |
| I/O processor            | Core                            | C2004                           |
|                          | Local RAM                       | 16 KB instruction<br>64 KB Data |
|                          | Single precision floating point | Yes                             |
|                          | LSP                             | Yes                             |
|                          | VLE                             | Yes                             |
|                          | Cache                           | 8 KB instruction                |
| HSM processor            | Core                            | C2002                           |
|                          | Security Grade                  | Evita-Full                      |
|                          | Symmetric-algorithm             | AES/DES3/SM1/SM4                |
|                          | Asymmetric-algorithm            | SM2/RSA-4096/ECC                |
|                          | Hash-algorithm                  | SHA/SHA3/SM3/MD5/RIPEMD160      |
| Main processor frequency |                                 | 300 MHz <sup>1</sup>            |
| I/O processor frequency  |                                 | 200 MHz                         |
| HSM processor frequency  |                                 | 100 MHz                         |
| MMU entries              |                                 | 0                               |
| MPU                      |                                 | Yes                             |
| Semaphores               |                                 | Yes                             |

Table 1. CCFC3007PT feature (continued)

| Feature                                                    | CCFC3007PT                                                   |
|------------------------------------------------------------|--------------------------------------------------------------|
| CRC channels                                               | 2                                                            |
| Software watchdog timer<br>(Task SWT/Safety SWT)           | 4 (2/2)                                                      |
| Core Nexus class                                           | 3+                                                           |
| Debug and calibration interface (DCI) / run control module | Yes                                                          |
| System SRAM                                                | 1.5MB                                                        |
| Flash memory                                               | 13056KB                                                      |
| Flash memory fetch accelerator                             | 4 × 256 bit                                                  |
| Data flash memory (EEPROM)                                 | 512 KB                                                       |
| Flash memory overlay RAM                                   | 16 KB                                                        |
| DMA channels                                               | 2 × 64                                                       |
| DMA Nexus Class                                            | 3+                                                           |
| RTC/API                                                    | 1                                                            |
| LINFlexD                                                   | 16                                                           |
| MCAN/TTCAN                                                 | 12/3                                                         |
| CANFD                                                      | 2                                                            |
| QSPI(4 bit width)                                          | 2                                                            |
| DSPI                                                       | 8                                                            |
| Microsecond bus downlink                                   | Yes                                                          |
| SENT bus                                                   | 15                                                           |
| CSENT bus                                                  | 15                                                           |
| I <sup>2</sup> C                                           | 2                                                            |
| I <sup>2</sup> S(SAI)                                      | 2                                                            |
| PSI5 bus                                                   | 5                                                            |
| PSI5-S UART-to-PSI5 interface                              | Yes                                                          |
| FlexRay                                                    | 2 × dual channel                                             |
| DWC_ether_qos                                              | MII / RMII/TSN                                               |
| System timers                                              | 8 PIT channels<br>3 AUTOSAR <sup>®</sup> (STM)<br>64-bit PIT |
| BOSCH <sup>®</sup> GTM Timer <sup>2</sup>                  | Yes                                                          |
| GTM RAM                                                    | 58 KB                                                        |
| Interrupt controller                                       | 926 sources                                                  |
| ADC (EQADC)                                                | 5 × 2                                                        |

Table 1. CCFC3007PT feature (continued)

| Feature                             | CCFC3007PT                             |
|-------------------------------------|----------------------------------------|
| eTPU channels                       | 96                                     |
| eMIOS channels                      | 2 × 16                                 |
| ADC (SD)                            | 8                                      |
| Temperature sensor                  | Yes                                    |
| Self test controller                | Yes                                    |
| PLL                                 | Dual PLL with FM                       |
| Integrated linear voltage regulator | None                                   |
| External power supplies             | 5 V<br>3.3 V <sup>3</sup><br>1.1 V     |
| Low-power modes                     | Stop mode<br>Slow mode<br>Standby mode |
| Packages                            | HQFP216/416 PBGA <sup>4</sup>          |

<sup>1</sup> Includes four user-programmable CPU cores and one safety core. The main computational shell consists of dual C3007 CPUs operating at 300 MHz with a third identical core running as a safety checker core in delayed lockstep mode with one of the dual C3007 cores. The I/O subsystem includes a CPU targeted at managing the peripherals. This is an C2004 CPU running at 200 MHz. The fifth CPU is an C2002 running at 100 MHz and is embedded in the Hardware Security Module. All CPUs are compatible with the Power Architecture.

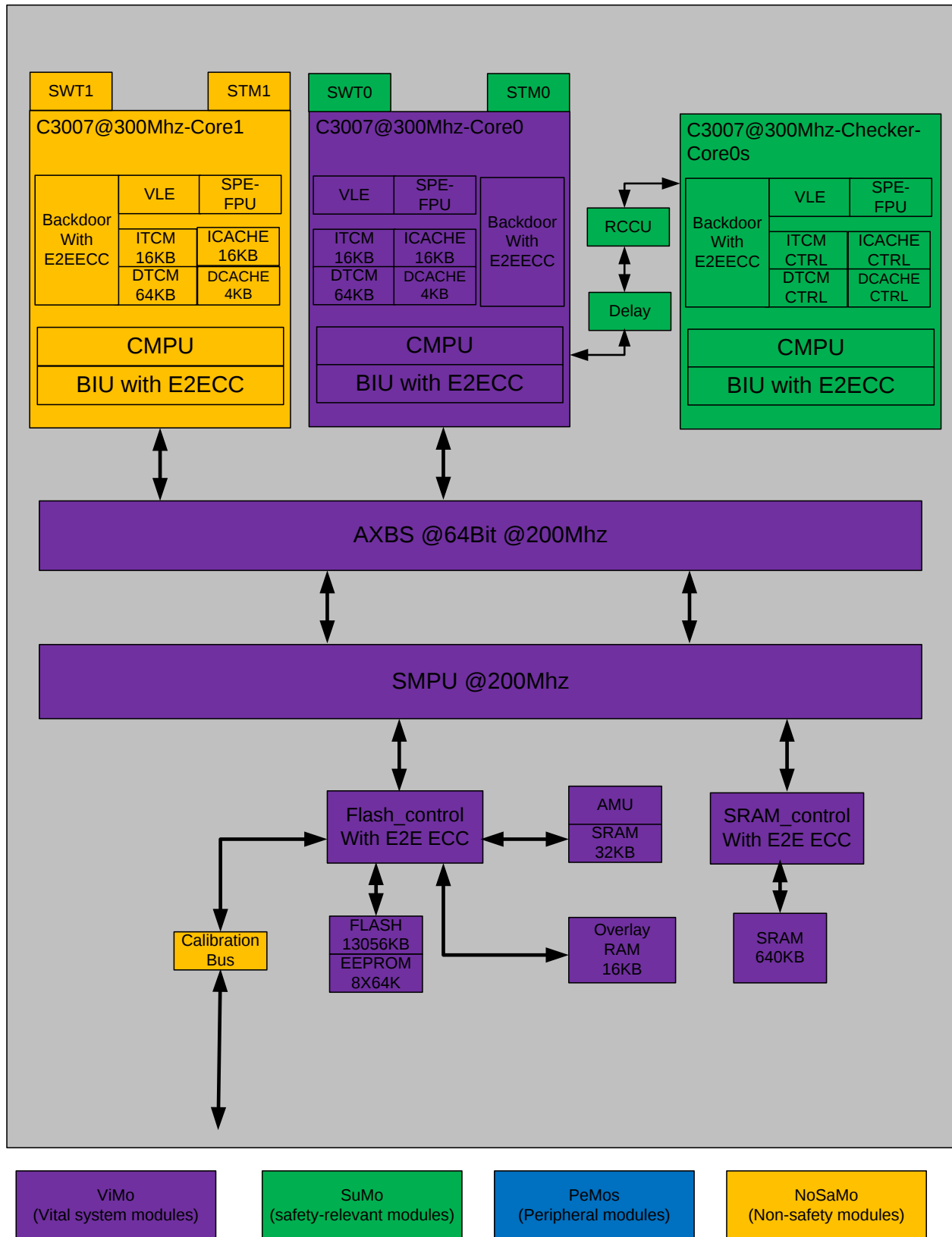
<sup>2</sup> BOSCH® is a registered trademark of Robert Bosch GmbH.

<sup>3</sup> 3.3V supply is for Ethernet phy interface

<sup>4</sup> TBD

## 1.4 Block diagram

The figures below show the top-level block diagrams.



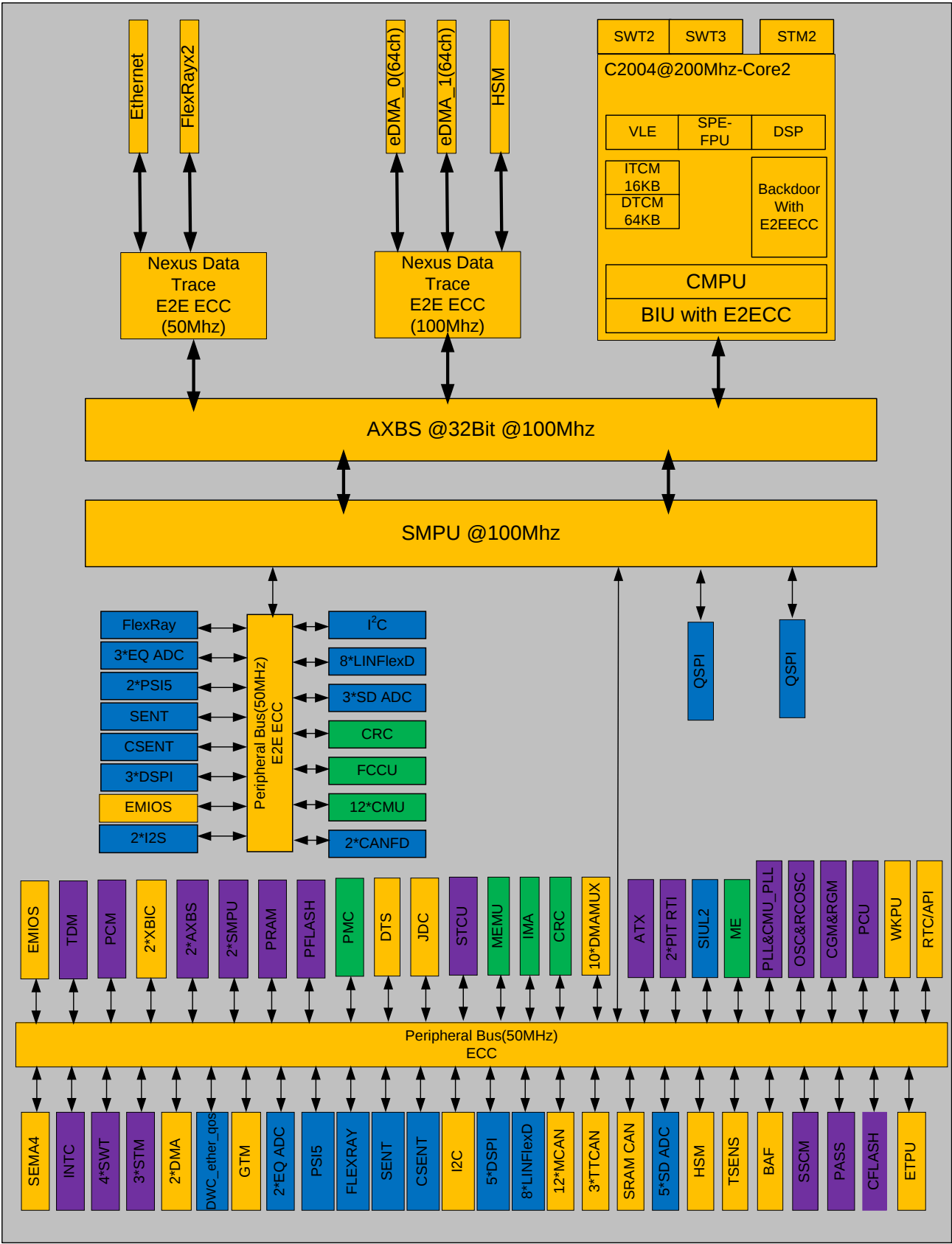


Figure 1. Block diagram

## 2 Package pinouts and signal descriptions

### 2.1 Package pinouts

The available BGA / HQFP pinouts and the ballmap are provided in CCFC3007PT pinmux and pinout.xlsx

The BGA ballmap package pinouts for the 416 production and emulation devices are shown in the table CCFC3007PTT192B4

### 2.2 Functional port pins

Please see the table CCFC3007PT\_pinmux in CCFC3007PT pinmux and pinout.xlsx

## 3 Electrical characteristics

### 3.1 Introduction

This section contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications.

In the tables where the device logic provides signals with their respective timing characteristics, the symbol “CC” (Controller Characteristics) is included in the “Symbol” column.

In the tables where the external system must provide signals with their respective timing characteristics to the device, the symbol “SR” (System Requirement) is included in the “Symbol” column.

#### NOTE

Within this document,  $V_{DD\_HV\_IO}$  refers to supply pins  $V_{DD\_HV\_IO\_MAIN}$ ,  $V_{DD\_HV\_IO\_FLEX}$  and  $V_{DD\_HV\_IO\_5V}$ .  $V_{DD\_HV\_ADV}$  refers to ADC supply pins  $V_{DD\_HV\_ADV\_S}$  and  $V_{DD\_HV\_ADV\_D}$ .  $V_{DD\_HV\_ADR}$  refers to ADC reference pins  $V_{DD\_HV\_ADR\_S}$  and  $V_{DD\_HV\_ADR\_D}$ .  $V_{SS\_HV\_ADV}$  refers to ADC ground pins  $V_{SS\_HV\_ADV\_S}$  and  $V_{SS\_HV\_ADV\_D}$ .  $V_{SS\_HV\_ADR}$  refers to ADC reference pins  $V_{SS\_HV\_ADR\_S}$  and  $V_{SS\_HV\_ADR\_D}$ .

### 3.2 Absolute maximum ratings

Table 6 describes the maximum ratings of the device.

**Table 2. Absolute maximum ratings<sup>1</sup>**

| Symbol                         |    | Parameter                                    | Conditions                                   | Value |     | Unit |
|--------------------------------|----|----------------------------------------------|----------------------------------------------|-------|-----|------|
|                                |    |                                              |                                              | Min   | Max |      |
| $V_{DD\_LV}$                   | SR | 1.1 V core supply voltage                    | —                                            | −0.3  | TBD | V    |
| $V_{DD\_HV\_IO}$               | SR | I/O supply voltage <sup>2</sup>              | —                                            | −0.3  | 6.0 | V    |
| $V_{DD\_HV\_PMC}$              | SR | Power Management Controller supply voltage   | —                                            | −0.3  | 6.0 | V    |
| $V_{DD\_HV\_FLA}$              | SR | Flash core voltage                           | —                                            | −0.3  | 3.6 | V    |
| $V_{SS\_HV\_ADV}$ <sup>3</sup> | SR | SAR and S/D ADC ground voltage               | Reference to V                               | −0.3  | 0.3 | V    |
| $V_{DD\_HV\_ADV}$ <sup>4</sup> | SR | SAR and S/D ADC supply voltage               | Reference to corresponding $V_{SS\_HV\_ADV}$ | −0.3  | 6.0 | V    |
| $V_{SS\_HV\_ADR}$ <sup>5</sup> | SR | SAR and S/D ADC low reference                | Reference to $V_{SS\_LV}$                    | −0.3  | 0.3 | V    |
| $V_{DD\_HV\_ADR}$ <sup>6</sup> | SR | SAR and S/D ADC high reference               | Reference to corresponding $V_{SS\_HV\_ADR}$ | −0.3  | 6.0 | V    |
| $V_{IN}$                       | SR | I/O input voltage range <sup>7</sup>         | —                                            | −0.3  | 6.0 | V    |
|                                |    |                                              | Relative to $V_{SS\_LV}$ <sup>8</sup>        | −0.3  | —   |      |
|                                |    |                                              | Relative to $V_{DD\_HV\_IO}$ <sup>8</sup>    | —     | 0.3 |      |
| $I_{INJD}$                     | SR | Maximum DC injection current for digital pad | Per pin, applies to all digital pins         | −5    | 5   | mA   |
| $I_{INJA}$                     | SR | Maximum DC injection current for analog pad  | Per pin, applies to all analog pins          | −5    | 5   | mA   |
| $I_{MAXD}$                     | SR | Maximum output DC current when driven        | Medium                                       | −3.8  | 3.8 | mA   |
|                                |    |                                              | Fast                                         | −20   | 20  |      |

<sup>1</sup> Functional operating conditions are given in the DC electrical specifications. Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the listed maxima may affect device reliability or cause permanent damage to the device.

<sup>2</sup>  $V_{DD\_HV\_IO}$  applies to  $V_{DD\_HV\_IO\_MAIN}$ ,  $V_{DD\_HV\_IO\_FLEX}$  and  $V_{DD\_HV\_IO\_5V}$  I/O power supplies.

- <sup>3</sup> Includes ADC grounds  $V_{SS\_HV\_ADV\_S}$  and  $V_{SS\_HV\_ADV\_D}$ .
- <sup>4</sup> Includes ADC supplies  $V_{DD\_HV\_ADV\_S}$  and  $V_{DD\_HV\_ADV\_D}$ .
- <sup>5</sup> Includes ADC low references  $V_{SS\_HV\_ADR\_S}$  and  $V_{SS\_HV\_ADR\_D}$ .
- <sup>6</sup> Includes ADC high references  $V_{DD\_HV\_ADR\_S}$  and  $V_{DD\_HV\_ADR\_D}$ .
- <sup>7</sup> The maximum input voltage on an I/O pin tracks with the associated I/O supply maximum. For the injection current condition on a pin, the voltage equals the supply plus the voltage drop across the internal ESD diode from I/O pin to supply. The diode voltage varies significantly across process and temperature, but a value of 0.3V can be used for nominal calculations.
- <sup>8</sup>  $V_{DD\_HV\_IO}/V_{SS\_HV\_IO}$  refers to supply pins and corresponding grounds:  $V_{DD\_HV\_IO\_MAIN}$ ,  $V_{DD\_HV\_IO\_FLEX}$ ,  $V_{DD\_HV\_IO\_5V}$ ,  $V_{DD\_HV\_OSC}$ ,  $V_{DD\_HV\_PMC}$ .

### 3.3 Electrostatic discharge (ESD)

The following table describes the ESD ratings of the device.

**Table 3. ESD ratings<sup>1,2</sup>**

| Parameter                                                     | Conditions  | Value | Unit |
|---------------------------------------------------------------|-------------|-------|------|
| ESD for Human Body Model (HBM) <sup>3</sup>                   | All pins    | 2000  | V    |
| ESD for field induced Charged Device Model (CDM) <sup>4</sup> | All pins    | 500   | V    |
|                                                               | Corner pins | 750   |      |

<sup>1</sup> All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

<sup>2</sup> Device failure is defined as: "If after exposure to ESD pulses, the device does not meet the device specification requirements, which includes the complete DC parametric and functional testing at room temperature and hot temperature. Maximum DC parametrics variation within 10% of maximum specification"

<sup>3</sup> This parameter tested in conformity with ANSI/ESDA/JEDEC JS-001 Electrostatic Discharge Sensitivity Testing

<sup>4</sup> This parameter tested in conformity with ANSI/ESD S5.3.1-2009 Charged Device Model - Component Level

### 3.4 Operating conditions

The following table describes the operating conditions for the device for which all specifications in the data sheet are valid, except where explicitly noted.

The device operating conditions must not be exceeded or the functionality of the device is not guaranteed.

**Table 4. Device operating conditions<sup>1</sup>**

| Symbol           |    | Parameter                               | Conditions                        | Value |     |     | Unit |
|------------------|----|-----------------------------------------|-----------------------------------|-------|-----|-----|------|
|                  |    |                                         |                                   | Min   | Typ | Max |      |
| Frequency        |    |                                         |                                   |       |     |     |      |
| f <sub>SYS</sub> | SR | Device operating frequency <sup>2</sup> | T <sub>J</sub> = −40 °C to 150 °C | —     | —   | 300 | MHz  |

Table 4. Device operating conditions<sup>1</sup> (continued)

| Symbol                                              |    | Parameter                                        | Conditions                       | Value                    |                          |                   | Unit |
|-----------------------------------------------------|----|--------------------------------------------------|----------------------------------|--------------------------|--------------------------|-------------------|------|
|                                                     |    |                                                  |                                  | Min                      | Typ                      | Max               |      |
| Temperature                                         |    |                                                  |                                  |                          |                          |                   |      |
| T <sub>J</sub>                                      | SR | Operating temperature range - junction           | —                                | −40.0                    | —                        | 150.0             | °C   |
| T <sub>A</sub> (T <sub>L</sub> to T <sub>H</sub> )  | SR | Ambient operating temperature range              | —                                | −40.0                    | —                        | 125.0             | °C   |
| Voltage                                             |    |                                                  |                                  |                          |                          |                   |      |
| V <sub>DD_LV</sub>                                  | SR | External core supply voltage <sup>3,4</sup>      | —                                | 0.99                     | —                        | 1.21              | V    |
| V <sub>DD_HV_IO_MAIN</sub>                          | SR | I/O supply voltage                               | —                                | 3.0                      | —                        | 5.5 <sup>12</sup> | V    |
| V <sub>DD_HV_IO_5v</sub>                            | SR | Ethernet I/O predriver supply voltage            | —                                | 4.5                      | —                        | 5.5               | V    |
| V <sub>DD_HV_IO_FLEX</sub>                          | SR | Ethernet I/O supply voltage                      | 5 V range                        | 3.0                      | —                        | 5.5               | V    |
|                                                     |    |                                                  | 3.3 V range                      | 3.0                      | —                        | 3.6               |      |
| V <sub>DD_HV_OSC</sub>                              | SR | Oscillator supply voltage                        |                                  | 3.0                      | —                        | 5.5               | V    |
| V <sub>DD_HV_PMC</sub>                              | SR | Power Management Controller (PMC) supply voltage | Full functionality               | 3.0 <sup>5</sup>         | —                        | 5.5               | V    |
| V <sub>DD_HV_ADV</sub>                              | SR | SARADC, SDADC Power supply voltage               | —                                | 3.0                      | —                        | 5.5               | V    |
| V <sub>DD_HV_ADR_D</sub>                            | SR | SD ADC supply reference voltage                  | Full SNR                         | 3.0                      |                          | 5.5               | V    |
| V <sub>DD_HV_ADR_D</sub> − V <sub>DD_HV_ADV_D</sub> | SR | SD ADC reference differential voltage            | —                                | —                        | —                        | 25                | mV   |
| V <sub>SS_HV_ADR_D</sub>                            | SR | SD ADC ground reference voltage                  | —                                | V <sub>SS_HV_ADV_D</sub> |                          |                   | V    |
| V <sub>SS_HV_ADR_D</sub> − V <sub>SS_HV_ADV_D</sub> | SR | V <sub>SS_HV_ADR_D</sub> differential voltage    | —                                | −25                      | —                        | 25                | mV   |
| V <sub>DD_HV_ADR_S</sub>                            | SR | SARADC reference                                 | —                                | 3.0                      | V <sub>DD_HV_ADV_S</sub> | 5.5               | V    |
| V <sub>SS_HV_ADR_S</sub>                            | SR | SAR ADC ground reference voltage                 | —                                | V <sub>SS_HV_ADV_S</sub> |                          |                   | V    |
| V <sub>DD_HV_ADR_S</sub> − V <sub>DD_HV_ADV_S</sub> | SR | SARADC reference differential voltage            | —                                | —                        | —                        | 25                | mV   |
| V <sub>SS_HV_ADR_S</sub> − V <sub>SS_HV_ADV_S</sub> | SR | V <sub>SS_HV_ADR_S</sub> differential voltage    | —                                | −25                      | —                        | 25                | mV   |
| V <sub>SS_HV_ADV</sub> − V <sub>SS_LV</sub>         | SR | V <sub>SS_HV_ADV</sub> differential voltage      | —                                | −25                      | —                        | 25                | mV   |
| V <sub>RAMP_LV</sub>                                | SR | Slew rate on core power supply pins              | —                                | —                        | —                        | 100               | V/ms |
| V <sub>RAMP_HV</sub>                                | SR | Slew rate on HV power supply pins                | —                                | —                        | —                        | 100               | V/ms |
| V <sub>por_rel</sub>                                | CC | POR release trip point                           | −40 °C < T <sub>J</sub> < 150 °C | —                        | 2.84                     | —                 | V    |
| V <sub>IN</sub>                                     | SR | I/O input voltage range                          | —                                | 0                        | —                        | 5.5               | V    |

- <sup>1</sup> The ranges in this table are design targets and actual data may vary in the given range.
- <sup>2</sup> Maximum operating frequency is applicable to the computational cores and platform for the device. See the Clocking chapter in the *CCFC3007PT Microcontroller Reference Manual* for more information on the clock limitations for the various IP blocks on the device.
- <sup>3</sup> Core voltage as measured on device pin to guarantee published silicon performance.
- <sup>4</sup> During power ramp, voltage measured on silicon might be lower. maximum performance is not guaranteed, but correct silicon operation is guaranteed. Refer to the Power Management and Reset Generation Module chapters in the *CCFC3007PT Microcontroller Reference Manual* for further information.
- <sup>5</sup> During power up operation, the minimum required voltage to come out of reset state is determined by the  $V_{\text{PORUP\_HV}}$  monitor, which is defined in the voltage monitor electrical characteristics table. Note that the  $V_{\text{PORUP\_HV}}$  monitor is connected to the  $V_{\text{DD\_HV\_IO\_MAIN}}$  physical I/O segment.

## 3.5 I/O pad electrical characteristics

### 3.5.1 I/O pad types

The device provides four main I/O pad types depending on the associated alternate functions:

- Medium pads—provide transition fast enough for the serial communication channels with controlled current to reduce electromagnetic emission.
- Fast pads—provide maximum speed. These are used for Ethernet communication interface IO.

Medium and Fast pads can use slow configuration to reduce electromagnetic emission, at the cost of reducing AC performance.

### 3.5.2 I/O input DC characteristics

Table 5 provides input DC electrical characteristics as described in Figure 2.

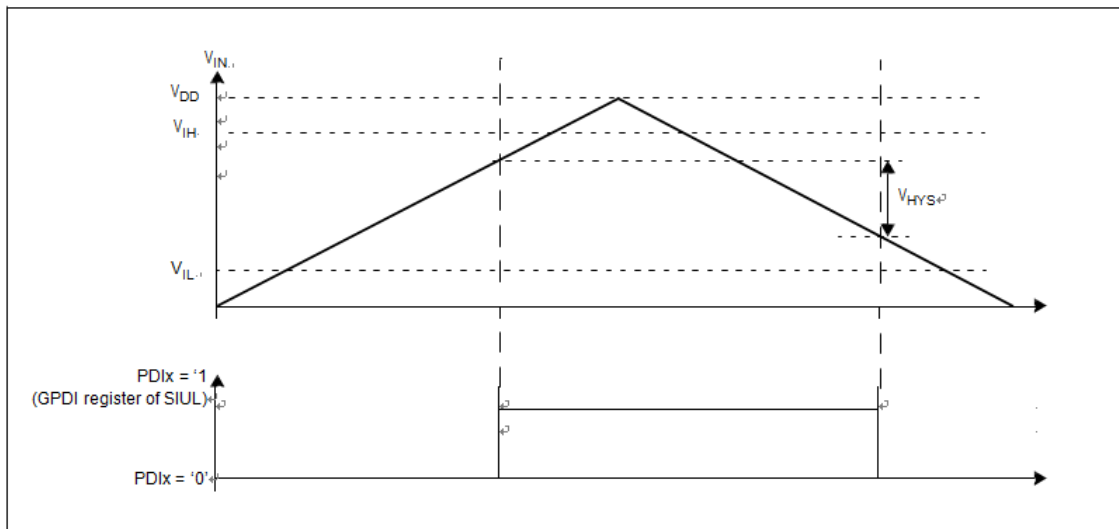


Figure 2. I/O input DC electrical characteristics definition

Table 5. I/O input DC electrical characteristics

| Symbol           |    | C                       | Parameter                               | Conditions <sup>1</sup>      |                         | Value               |      |                       | Unit |
|------------------|----|-------------------------|-----------------------------------------|------------------------------|-------------------------|---------------------|------|-----------------------|------|
|                  |    |                         |                                         |                              |                         | Min                 | Typ  | Max                   |      |
| V <sub>IH</sub>  | SR | P                       | Input high level CMOS (Schmitt Trigger) | —                            |                         | 0.65V <sub>DD</sub> | —    | V <sub>DD</sub> + 0.4 | V    |
| V <sub>IL</sub>  | SR | P                       | Input low level CMOS (Schmitt Trigger)  | —                            |                         | −0.4                | —    | 0.35V <sub>DD</sub>   | V    |
| V <sub>HYS</sub> | CC | C                       | Input hysteresis CMOS (Schmitt Trigger) | —                            |                         | 0.1V <sub>DD</sub>  | —    | —                     | V    |
| I <sub>LKG</sub> | CC | D                       | Digital input leakage                   | No injection on adjacent pin | T <sub>A</sub> = −40 °C | —                   | 2    | 200                   | nA   |
|                  |    | T <sub>A</sub> = 25 °C  |                                         |                              | —                       | 2                   | 200  |                       |      |
|                  |    | T <sub>A</sub> = 85 °C  |                                         |                              | —                       | 5                   | 300  |                       |      |
|                  |    | T <sub>A</sub> = 105 °C |                                         |                              | —                       | 12                  | 500  |                       |      |
|                  |    | T <sub>A</sub> = 125 °C |                                         |                              | —                       | 70                  | 1000 |                       |      |

<sup>1</sup>  $V_{DD}$  stands for  $V_{DD\_HV\_IO\_MAIN}$ ,  $V_{DD} = 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ °C}$ , unless otherwise specified

### 3.5.3 I/O output DC characteristics

The following tables provide DC characteristics for bidirectional pads:

- [Table 6](#) provides weak pull characteristics for I/O pads when in MEDIUM configuration
- [Table 7](#) provides weak pull characteristics for I/O pads when in FAST configuration
- [Table 8](#) provides output driver characteristics for I/O pads when in MEDIUM configuration.
- [Table 9](#) provides output driver characteristics for I/O pads when in FAST configuration.

Table 6. Medium I/O pull-up/pull-down DC electrical characteristics

| Symbol           |    | C | Parameter                             | Conditions <sup>1</sup>                                           |                          | Value |     |     | Unit |
|------------------|----|---|---------------------------------------|-------------------------------------------------------------------|--------------------------|-------|-----|-----|------|
|                  |    |   |                                       |                                                                   |                          | Min   | Typ | Max |      |
| I <sub>WPU</sub> | CC | P | Weak pull-up current absolute value   | V <sub>IN</sub> = V <sub>IL</sub> , V <sub>DD</sub> = 5.0 V ± 10% | PAD3V5V = 0              | 10    | —   | 150 | μA   |
|                  |    | C |                                       |                                                                   | PAD3V5V = 1 <sup>2</sup> | 10    | —   | 250 |      |
| I <sub>WPD</sub> | CC | P | Weak pull-down current absolute value | V <sub>IN</sub> = V <sub>IH</sub> , V <sub>DD</sub> = 5.0 V ± 10% | PAD3V5V = 0              | 10    | —   | 150 | μA   |
|                  |    | C |                                       |                                                                   | PAD3V5V = 1              | 10    | —   | 250 |      |

<sup>1</sup>  $V_{DD}$  stands for  $V_{DD\_HV\_IO\_MAIN}$ ,  $T_A = -40$  to  $125\text{ °C}$ , unless otherwise specified.

**Table 7. FAST I/O pull-up/pull-down DC electrical characteristics**

| Symbol           |    | C | Parameter                                | Conditions <sup>1</sup>           |                                          | Value |     |     | Unit |
|------------------|----|---|------------------------------------------|-----------------------------------|------------------------------------------|-------|-----|-----|------|
|                  |    |   |                                          |                                   |                                          | Min   | Typ | Max |      |
| I <sub>WPU</sub> | CC | P | Weak pull-up current<br>absolute value   | V <sub>IN</sub> = V <sub>IL</sub> | V <sub>DD_HV_IO_FLEX</sub> = 5.0 V ± 10% | 79    | —   | 119 | μA   |
|                  |    | C |                                          |                                   | V <sub>DD_HV_IO_FLEX</sub> = 3.3 V ± 10% | 30    | —   | 66  |      |
| I <sub>WPD</sub> | CC | P | Weak pull-down current<br>absolute value | V <sub>IN</sub> = V <sub>IH</sub> | V <sub>DD_HV_IO_FLEX</sub> = 5.0 V ± 10% | 82    | —   | 119 | μA   |
|                  |    | C |                                          |                                   | V <sub>DD_HV_IO_FLEX</sub> = 3.3 V ± 10% | 31    | —   | 72  |      |

<sup>1</sup> T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

**Table 8. MEDIUM configuration output buffer electrical characteristics**

| Symbol          |    | C | Parameter            | Conditions <sup>1</sup> |                                                                                     | Value              |     |                    | Unit |
|-----------------|----|---|----------------------|-------------------------|-------------------------------------------------------------------------------------|--------------------|-----|--------------------|------|
|                 |    |   |                      |                         |                                                                                     | Min                | Typ | Max                |      |
| V <sub>OH</sub> | CC | C | Output high level    | Push Pull               | I <sub>OH</sub> = -3.8 mA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0            | 0.8V <sub>DD</sub> | —   | —                  | V    |
|                 |    | P | MEDIUM configuration |                         | I <sub>OH</sub> = -2 mA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0(recommended) | 0.8V <sub>DD</sub> | —   | —                  |      |
|                 |    | C |                      |                         | I <sub>OH</sub> = -1 mA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 1 <sup>2</sup> | 0.8V <sub>DD</sub> | —   | —                  |      |
|                 |    | C |                      |                         | I <sub>OH</sub> = -100 μA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0            | 0.8V <sub>DD</sub> | —   | —                  |      |
| V <sub>OL</sub> | CC | C | Output low level     | Push Pull               | I <sub>OL</sub> = 3.8 mA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0             | —                  | —   | 0.2V <sub>DD</sub> | V    |
|                 |    | P | MEDIUM configuration |                         | I <sub>OL</sub> = 2 mA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0(recommended)  | —                  | —   | 0.1V <sub>DD</sub> |      |
|                 |    | C |                      |                         | I <sub>OL</sub> = 1 mA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 1               | —                  | —   | 0.1V <sub>DD</sub> |      |
|                 |    | C |                      |                         | I <sub>OL</sub> = 100 μA, V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0             | —                  | —   | 0.1V <sub>DD</sub> |      |

<sup>1</sup> V<sub>DD</sub> stands for V<sub>DD\_HV\_IO\_MAIN</sub>; T<sub>A</sub> = -40 to 125 °C, unless otherwise specified

Table 9. FAST configuration output buffer electrical characteristics

| Symbol          | C  | Parameter                                    | Conditions <sup>1</sup>               | Value                             |     |                                   | Unit |
|-----------------|----|----------------------------------------------|---------------------------------------|-----------------------------------|-----|-----------------------------------|------|
|                 |    |                                              |                                       | Min                               | Typ | Max                               |      |
| V <sub>OH</sub> | CC | P<br>Output high level<br>FAST configuration | Push Pull<br>I <sub>OH</sub> = -20 mA | 0.8<br>V <sub>DD_HV_IO_FLEX</sub> | —   | —                                 | V    |
| V <sub>OL</sub> | CC | P<br>Output low level<br>FAST configuration  | Push Pull<br>I <sub>OL</sub> = 20 mA  | —                                 | —   | 0.2<br>V <sub>DD_HV_IO_FLEX</sub> | V    |

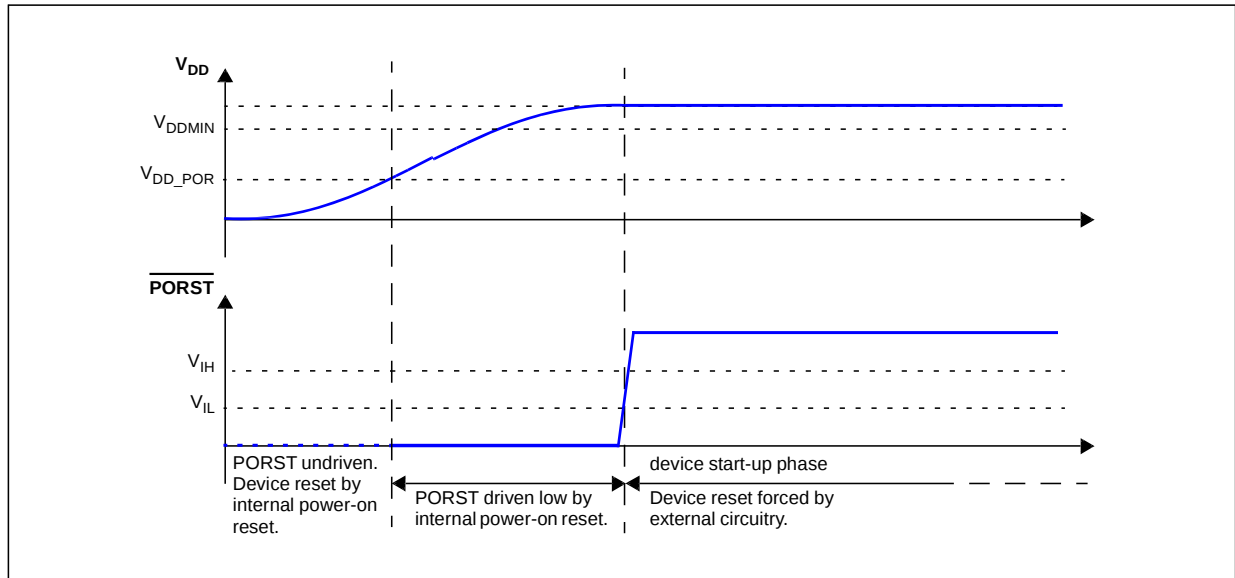
<sup>1</sup> V<sub>DD\_HV\_IO\_FLEX</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified

### 3.6 Reset pad ( $\overline{\text{PORST}}$ , $\overline{\text{ESR0}}$ ) electrical characteristics

The device implements a dedicated bidirectional reset pin ( $\overline{\text{PORST}}$ ).

#### NOTE

$\overline{\text{PORST}}$  pin does not require active control. It is possible to implement an external pull-up to ensure correct reset exit sequence. Recommended value is 4.7 k $\Omega$ .



**Figure 3. Start-up reset requirements**

Figure 4 describes device behavior depending on supply signal on  $\overline{\text{PORST}}$ :

1.  $\overline{\text{PORST}}$  low pulse amplitude is too low—it is filtered by input buffer hysteresis. Device remains in current state.
2.  $\overline{\text{PORST}}$  low pulse duration is too short—it is filtered by a low pass filter. Device remains in current state.
3.  $\overline{\text{PORST}}$  low pulse generates a reset:
  - a)  $\overline{\text{PORST}}$  low but initially filtered during at least  $W_{\text{FRST}}$ . Device remains initially in current state.
  - b)  $\overline{\text{PORST}}$  potentially filtered until  $W_{\text{NFRST}}$ . Device state is unknown: it may either be reset or remains in current state depending on other factors (temperature, voltage, device).
  - c)  $\overline{\text{PORST}}$  asserted for longer than  $W_{\text{NFRST}}$ . Device is under reset.

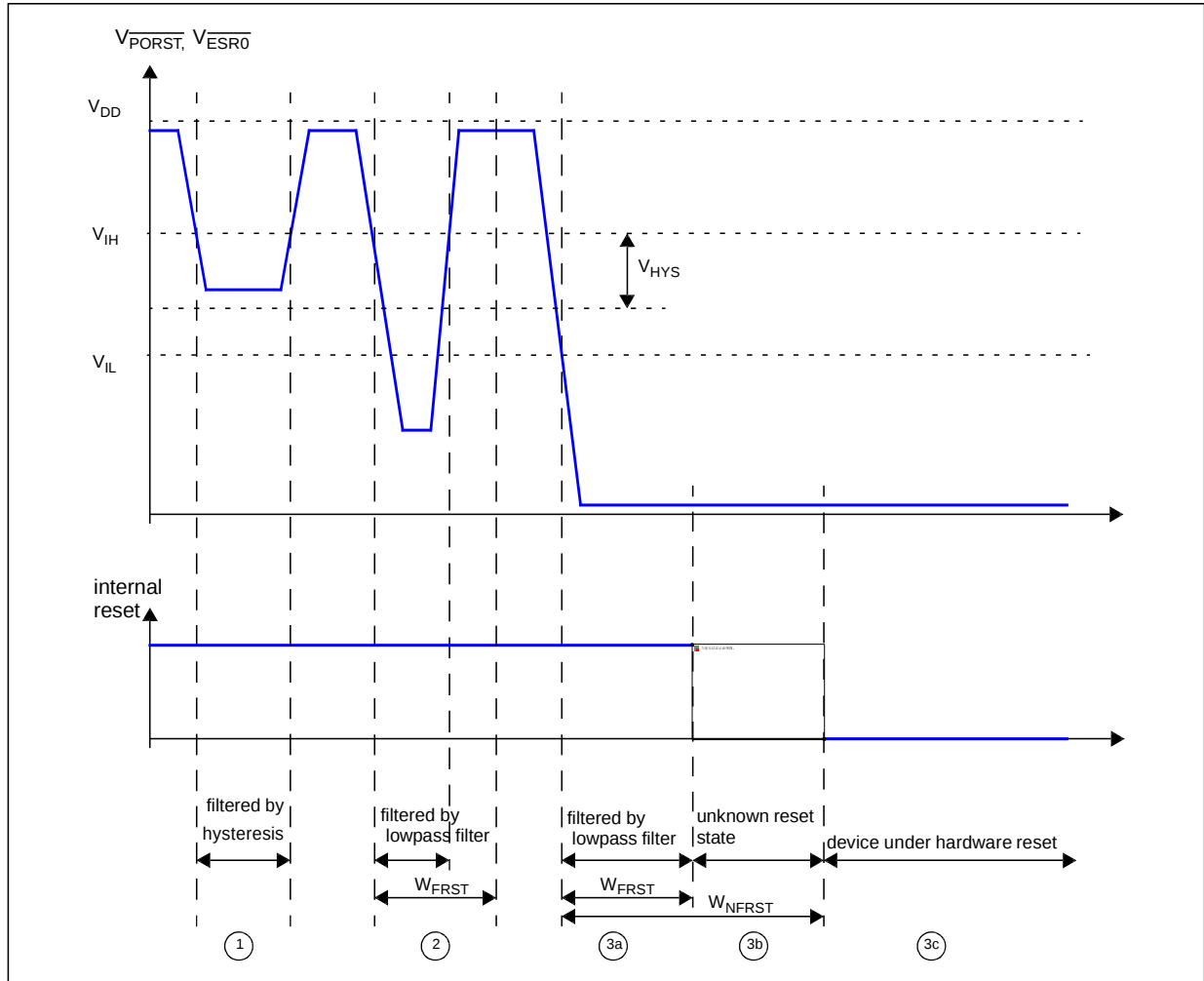


Figure 4. Noise filtering on reset signal

Table 10. Reset electrical characteristics

| Symbol              | Parameter                                         | Conditions | Value <sup>1</sup> |     |                             | Unit |
|---------------------|---------------------------------------------------|------------|--------------------|-----|-----------------------------|------|
|                     |                                                   |            | Min                | Typ | Max                         |      |
| V <sub>IH</sub>     | SR Input high level TTL (Schmitt trigger)         | —          | 2.2                | —   | V <sub>DD_HV_IO</sub> + 0.4 | V    |
| V <sub>IL</sub>     | SR Input low level TTL (Schmitt trigger)          | —          | −0.4               | —   | 0.8                         | V    |
| V <sub>HYS</sub>    | CC Input hysteresis TTL (Schmitt trigger)         | —          | 300                | —   | —                           | mV   |
| V <sub>DD_POR</sub> | CC Minimum supply for strong pull-down activation | —          | —                  | —   | 1.2                         | V    |

Table 10. Reset electrical characteristics (continued)

| Symbol      | Parameter | Conditions                                                                                                                                   | Value <sup>1</sup> |     |     | Unit          |
|-------------|-----------|----------------------------------------------------------------------------------------------------------------------------------------------|--------------------|-----|-----|---------------|
|             |           |                                                                                                                                              | Min                | Typ | Max |               |
| $I_{OL\_R}$ | CC        | Strong pull-down current <sup>2</sup><br>Device under power-on reset<br>$V_{DD\_HV\_IO} = V_{DD\_POR}$ ,<br>$V_{OL} = 0.35 * V_{DD\_HV\_IO}$ | 0.2                | —   | —   | mA            |
|             |           | Device under power-on reset<br>$3.0\text{ V} < V_{DD\_HV\_IO} < 5.5\text{ V}$ ,<br>$V_{OL} > 0.9\text{ V}$                                   | 11                 | —   | —   | mA            |
| $ I_{WPU} $ | CC        | Weak pull-up current absolute value<br>ESR0 pin<br>$V_{IN} = 0.69 * V_{DD\_HV\_IO}$                                                          | 23                 | —   | —   | $\mu\text{A}$ |
|             |           | ESR0 pin<br>$V_{IN} = 0.49 * V_{DD\_HV\_IO}$                                                                                                 | —                  | —   | 82  |               |
| $ I_{WPD} $ | CC        | Weak pull-down current absolute value<br>PORST pin<br>$V_{IN} = 0.69 * V_{DD\_HV\_IO}$                                                       | —                  | —   | 130 | $\mu\text{A}$ |
|             |           | PORST pin<br>$V_{IN} = 0.49 * V_{DD\_HV\_IO}$                                                                                                | 40                 | —   | —   |               |
| $W_{FRST}$  | SR        | PORST and ESR0 input filtered pulse                                                                                                          | —                  | —   | 500 | ns            |
| $W_{NFRST}$ | SR        | PORST and ESR0 input not filtered pulse                                                                                                      | 2000               | —   | —   | ns            |
| $W_{FNMI}$  | SR        | ESR1 input filtered pulse                                                                                                                    | —                  | —   | 40  | ns            |
| $W_{NFNMI}$ | SR        | ESR1 input not filtered pulse                                                                                                                | 1000               | —   | —   | ns            |

<sup>1</sup> An external 4.7 KOhm pull-up resistor is recommended to be used with the PORST and ESR0 pins for fast negation of the signals.

<sup>2</sup>  $I_{OL\_R}$  applies to both PORST and ESR0: Strong pull-down is active on PHASE0 for PORST. Strong pull-down is active on PHASE0, PHASE1, PHASE2, and the beginning of PHASE3 for ESR0.

### NOTE

$\overline{\text{PORST}}$  can optionally be connected to an external power-on supply circuitry.

### NOTE

No restrictions exist on reset signal slew rate apart from absolute maximum rating compliance.

### 3.7 Oscillator and FMPLL

The Reference PLL (PLL0) and the System PLL (PLL1) generate the system and auxiliary clocks from the main oscillator driver.

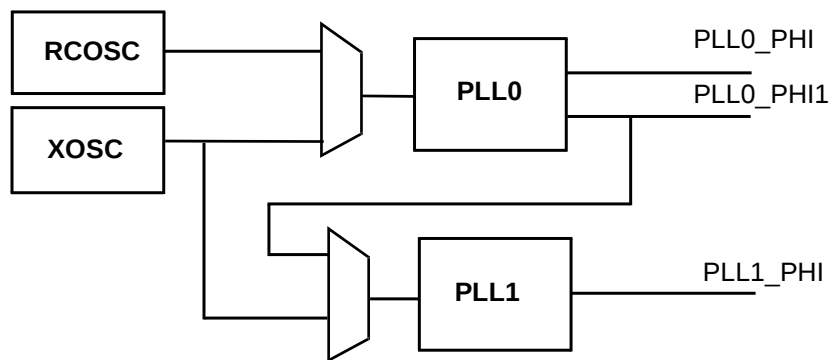


Figure 5. PLL integration

Table 11. PLL0 electrical characteristics<sup>1</sup>

| Symbol                         |    | Parameter             | Conditions                         | Value |     |      | Unit          |
|--------------------------------|----|-----------------------|------------------------------------|-------|-----|------|---------------|
|                                |    |                       |                                    | Min   | Typ | Max  |               |
| $f_{\text{PLL0IN}}$            | SR | PLL0 input clock      | —                                  | 8     | —   | 44   | MHz           |
| $f_{\text{PLL0VCO}}$           | CC | PLL0 VCO frequency    | —                                  | 600   | —   | 1250 | MHz           |
| $f_{\text{PLL0PHI}}$           | CC | PLL0 output frequency | —                                  | 4.762 | —   | 400  | MHz           |
| $t_{\text{PLL0LOCK}}$          | CC | PLL0 lock time        | —                                  | —     | —   | 110  | $\mu\text{s}$ |
| $ \Delta_{\text{PLL0PHISPJ}} $ | CC | PLL0 period jitter    | $f_{\text{VCO}} = 800 \text{ MHz}$ | —     | 50  | 200  | ps            |
| $D_{\text{TC}}$                | CC | Output duty cycle     |                                    | 45    | 50  | 55   | %             |

<sup>1</sup>  $V_{\text{DD\_HV\_OSC}} = 5.0 \text{ V} \pm 10\%$ ,  $T_{\text{A}} = -40 \text{ to } 125 \text{ }^{\circ}\text{C}$ , unless otherwise specified

Table 12. PLL1 electrical characteristics<sup>1</sup>

| Symbol                         |    | Parameter                 | Conditions                         | Value |     |      | Unit          |
|--------------------------------|----|---------------------------|------------------------------------|-------|-----|------|---------------|
|                                |    |                           |                                    | Min   | Typ | Max  |               |
| $f_{\text{PLL0IN}}$            | SR | PLL1 input clock          | —                                  | 38    | —   | 78   | MHz           |
| $f_{\text{CLK\_PFD}}$          | CC | PFD input clock frequency | —                                  | 19    | —   | 39   | MHz           |
| $f_{\text{PLL0VCO}}$           | CC | PLL1 VCO frequency        | —                                  | 600   | —   | 1250 | MHz           |
| $t_{\text{PLL0LOCK}}$          | CC | PLL1 lock time            | —                                  | —     | —   | 100  | $\mu\text{s}$ |
| $ \Delta_{\text{PLL0PHISPJ}} $ | CC | PLL1 period jitter        | $f_{\text{VCO}} = 800 \text{ MHz}$ | —     | 50  | 200  | ps            |
| $D_{\text{TC}}$                | CC | Output duty cycle         |                                    | 45    | 50  | 55   | %             |

<sup>1</sup>  $V_{\text{DD\_HV\_OSC}} = 5.0 \text{ V} \pm 10\%$ ,  $T_{\text{A}} = -40 \text{ to } 125 \text{ }^{\circ}\text{C}$ , unless otherwise specified

Table 13. External Oscillator electrical specifications<sup>1</sup>

| Symbol        |    | Parameter                                                            | Conditions                                                           | Value           |                 | Unit |
|---------------|----|----------------------------------------------------------------------|----------------------------------------------------------------------|-----------------|-----------------|------|
|               |    |                                                                      |                                                                      | Min             | Max             |      |
| $f_{XTAL}$    | CC | Crystal Frequency Range <sup>2</sup>                                 | —                                                                    | 4               | 8               | MHz  |
|               |    |                                                                      | —                                                                    | >8              | 20              |      |
|               |    |                                                                      | —                                                                    | >20             | 40              |      |
| $t_{cst}$     | CC | Crystal start-up time <sup>3,4</sup>                                 | $T_J = 150\text{ }^{\circ}\text{C}$                                  | —               | 5               | ms   |
| $t_{rec}$     | CC | Crystal recovery time <sup>5</sup>                                   | —                                                                    | —               | 0.5             | ms   |
| $V_{IHEXT}$   | CC | EXTAL input high voltage <sup>6,7</sup><br>(External Clock Input)    | $V_{REF} = 0.28 * V_{DD\_HV\_IO\_JTAG}$                              | $V_{REF} + 0.6$ | —               | V    |
| $V_{ILEXT}$   | CC | EXTAL input low voltage <sup>6,7</sup><br>(External Clock Input)     | $V_{REF} = 0.28 * V_{DD\_HV\_IO\_JTAG}$                              | —               | $V_{REF} - 0.6$ | V    |
| $C_{S\_xtal}$ | CC | Total on-chip stray capacitance<br>on XTAL/EXTAL pins <sup>8</sup>   | BGA416, BGA512                                                       | 8               | 8.6             | pF   |
| $V_{EXTAL}$   | CC | Oscillation Amplitude on the<br>EXTAL pin after startup <sup>9</sup> | $T_J = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$ | 0.5             | 1.6             | V    |
| $V_{HYS}$     | CC | Comparator Hysteresis                                                | $T_J = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$ | 0.1             | 1.0             | V    |
| $I_{XTAL}$    | CC | XTAL current <sup>13,10</sup>                                        | $T_J = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$ | —               | 14              | mA   |

<sup>1</sup> All oscillator specifications are valid for  $V_{DD\_HV\_OSC} = 4.5\text{ V} - 5.5\text{ V}$ .

### 3.8 ADC specifications

Table 14. ADC input leakage current

| Symbol           | C  | Parameter | Conditions              | Value |     |     | Unit |
|------------------|----|-----------|-------------------------|-------|-----|-----|------|
|                  |    |           |                         | Min   | Typ | Max |      |
| I <sub>LKG</sub> | CC | D         | T <sub>A</sub> = -40 °C | —     | 1   | 70  | nA   |
|                  |    |           | T <sub>A</sub> = 25 °C  |       | 1   | 70  |      |
|                  |    |           | T <sub>A</sub> = 85 °C  |       | 3   | 100 |      |
|                  |    |           | T <sub>A</sub> = 105 °C |       | 8   | 200 |      |
|                  |    |           | T <sub>A</sub> = 125 °C |       | 45  | 400 |      |

Table 15. SARADC conversion characteristics

| Symbol                  | C  | Parameter | Conditions <sup>1</sup>                                                                             | Value                 |     |                       | Unit |
|-------------------------|----|-----------|-----------------------------------------------------------------------------------------------------|-----------------------|-----|-----------------------|------|
|                         |    |           |                                                                                                     | Min                   | Typ | Max                   |      |
| V <sub>AINx</sub>       | SR | —         | Analog input voltage <sup>3</sup>                                                                   | —                     | —   | —                     | V    |
| V <sub>SS_HV_AD R</sub> | SR | —         | Voltage on VSS_HV_ADR (ADC reference) pin with respect to ground (V <sub>SS_LV</sub> ) <sup>2</sup> | -0.1                  | —   | 0.1                   | V    |
| V <sub>DD_HV_AD R</sub> | SR | —         | Voltage on VDD_HV_ADR pin (ADC reference) with respect to ground (V <sub>SS_LV</sub> )              | V <sub>DD</sub> - 0.1 | —   | V <sub>DD</sub> + 0.1 | V    |
| I <sub>ADCpwr</sub>     | SR | —         | ADC consumption in power down mode                                                                  | —                     | —   | 50                    | μA   |
| I <sub>ADCrun</sub>     | SR | —         | ADC consumption in running mode                                                                     | —                     | —   | 6                     | mA   |
|                         |    |           | V <sub>DD_HV_ADV</sub> = 5 V                                                                        | 3.33                  | —   | 32 + 4%               | MHz  |
| t <sub>ADC_PU</sub>     | SR | —         | ADC power up delay                                                                                  | —                     | —   | 1.5                   | μs   |
| t <sub>ADC_S</sub>      | CC | T         | Sampling time <sup>4</sup> V <sub>DD_HV_ADV</sub> = 5 V                                             | 600                   | —   | —                     | ns   |
|                         |    |           | Sampling time <sup>4</sup> V <sub>DD_HV_ADV</sub> = 5 V                                             | 500                   | —   | —                     |      |
|                         |    |           | Sampling time <sup>4</sup> V <sub>DD_HV_ADV</sub> = 5 V                                             | —                     | —   | 76.2                  | μs   |
|                         |    |           | Sampling time <sup>4</sup> V <sub>DD_HV_ADV</sub> = 5 V                                             | —                     | —   | 76.2                  |      |
| t <sub>ADC_C</sub>      | CC | P         | Conversion time <sup>5</sup> V <sub>DD_HV_ADV</sub> = 5 V                                           | 2.4                   | —   | —                     | μs   |
|                         |    |           | Conversion time <sup>5</sup> V <sub>DD_HV_ADV</sub> = 5 V                                           | 1.5                   | —   | —                     | μs   |

**Electrical characteristics**

|                     |    |   |                                                                    |                                                                                                                   |     |     |     |     |
|---------------------|----|---|--------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------|-----|-----|-----|-----|
|                     |    |   | Conversion time <sup>5</sup> $V_{DD\_HV\_ADV}$<br>= 5 V            | $f_{ADC1} = 13.33$ MHz,<br>INPCMP = 0                                                                             | —   | —   | 3.6 | μs  |
|                     |    |   | Conversion time <sup>5</sup> $V_{DD\_HV\_ADV}$<br>= 5 V            | $f_{ADC1} = 13.33$ MHz,<br>INPCMP = 0                                                                             | —   | —   | 3.6 | μs  |
| $\Delta_{ADC\_SYS}$ | SR | — | ADC digital clock duty cycle                                       | ADCLKSEL = 1 <sup>6</sup>                                                                                         | 45  | —   | 55  | %   |
| $C_S$               | CC | D | ADC input sampling<br>capacitance                                  | —                                                                                                                 | —   | —   | 5   | pF  |
| $C_{P1}$            | CC | D | ADC_1 input pin capacitance 1                                      | —                                                                                                                 | —   | —   | 3   | pF  |
| $C_{P2}$            | CC | D | ADC_1 input pin capacitance 2                                      | —                                                                                                                 | —   | —   | 1   | pF  |
| $C_{P3}$            | CC | D | ADC_1 input pin capacitance 3                                      | —                                                                                                                 | —   | —   | 1.5 | pF  |
| $R_{SW1}$           | CC | D | Internal resistance of analog<br>source                            | —                                                                                                                 | —   | —   | 1   | kΩ  |
| $R_{SW2}$           | CC | D | Internal resistance of analog<br>source                            | —                                                                                                                 | —   | —   | 2   | kΩ  |
| $R_{AD}$            | CC | D | Internal resistance of analog<br>source                            | —                                                                                                                 | —   | —   | 0.3 | kΩ  |
| $I_{INJ}$           | SR | — | Input current Injection                                            | Current injection on one ADC_1<br>input, different from the converted<br>one, $V_{DD\_HV\_ADR} = 5.0$ V $\pm$ 10% | −5  | —   | 5   | mA  |
| INLP                | CC | T | Absolute integral nonlinearity –<br>Precise channels               | No overload                                                                                                       | —   | 1   | 3   | LSB |
| INLX                | CC | T | Absolute integral nonlinearity –<br>Extended channels              | No overload                                                                                                       | —   | 1.5 | 5   | LSB |
| DNL                 | CC | T | Absolute differential<br>nonlinearity                              | No overload                                                                                                       | —   | 0.5 | 1   | LSB |
| $E_O$               | CC | T | Absolute offset error                                              | —                                                                                                                 | —   | 2   | —   | LSB |
| $E_G$               | CC | T | Absolute gain error                                                | —                                                                                                                 | —   | 2   | —   | LSB |
| TUEP <sup>7</sup>   | CC | P | Total unadjusted error for<br>precise channels, input only<br>pins | Without current injection                                                                                         | −6  | —   | 6   | LSB |
|                     |    | T |                                                                    | With current injection                                                                                            | −8  | —   | 8   |     |
| TUEX <sup>7</sup>   | CC | T | Total unadjusted error for<br>extended channel                     | Without current injection                                                                                         | −10 | —   | 10  | LSB |
|                     |    |   |                                                                    | With current injection                                                                                            | −12 | —   | 12  |     |

## Electrical characteristics

- <sup>1</sup>  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^{\circ}\text{C}$ , unless otherwise specified
- <sup>2</sup> Analog and digital  $V_{SS}$  **must** be common (to be tied together externally).
- <sup>3</sup>  $V_{AINX}$  may exceed  $V_{SS\_ADC1}$  and  $V_{DD\_ADC1}$  limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0xFF.
- <sup>4</sup> During the sampling time the input capacitance  $C_S$  can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within  $t_{ADC1\_S}$ . After the end of the sampling time  $t_{ADC1\_S}$ , changes of the analog input voltage have no effect on the conversion result. Values for the sampling clock  $t_{ADC1\_S}$  depend on programming.
- <sup>5</sup> This parameter does not include the sampling time  $t_{ADC1\_S}$ , but only the time for determining the digital result and the time to load the result's register with the conversion result.
- <sup>6</sup> Duty cycle is ensured by using system clock without prescaling. When  $ADCLKSEL = 0$ , the duty cycle is ensured by internal divider by 2.
- <sup>7</sup> Total Unadjusted Error: The maximum error that occurs without adjusting Offset and Gain errors. This error is a combination of Offset, Gain and Integral Linearity errors.

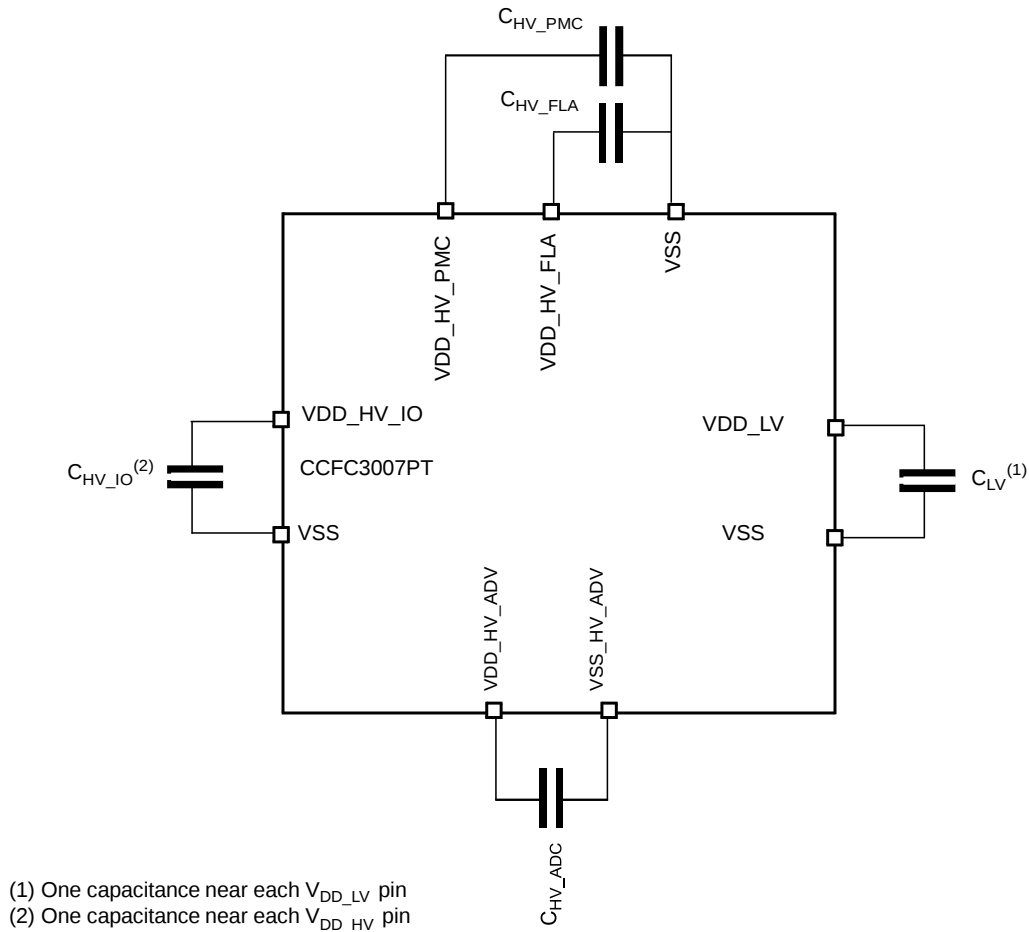
## 3.9 Power management: PMC, POR/LVD, sequencing

### 3.9.1 Power management electrical characteristics

The power management module monitors the different power supplies. It also generates the internal supplies that are required for correct device functionality. The power management is supplied by the  $V_{DD\_HV\_PMC}$  supply (see [Table 8](#)).

### 3.9.2 Power management integration

In order to ensure correct functionality of the device, it is recommended to follow below integration scheme.



**Figure 6. Recommended supply pin circuits**

## Electrical characteristics

The following table describes the supply stability capacitances required on the device for proper operation.

**Table 16. Device power supply integration**

| Symbol               |    | Parameter                                                          |                                          | Conditions                            | Value <sup>1</sup> |     |     | Unit |
|----------------------|----|--------------------------------------------------------------------|------------------------------------------|---------------------------------------|--------------------|-----|-----|------|
|                      |    |                                                                    |                                          |                                       | Min                | Typ | Max |      |
| C <sub>LV</sub>      | SR | Minimum VDD_LV external capacitance <sup>2</sup>                   | Bulk capacitance                         | External regulator bandwidth > 20 KHz | 10                 | —   | —   | μF   |
|                      |    |                                                                    | Total bypass capacitance at external pin |                                       | See Note 3         | —   | —   |      |
| C <sub>HV_IO</sub>   | SR | Minimum VDD_HV_IO external capacitance                             |                                          | —                                     | 4.7                | —   | —   | μF   |
| C <sub>HV_FL A</sub> | SR | Minimum VDD_HV_FL A external capacitance <sup>4</sup>              |                                          | —                                     | 0.75               | 1.0 | —   | μF   |
| C <sub>HV_PMC</sub>  | SR | Minimum V <sub>DD_HV_PMC</sub> External Capacitance <sup>5 6</sup> |                                          | —                                     | 2.2                | 4.7 | —   | μF   |
| C <sub>HV_ADC</sub>  | SR | Minimum V <sub>DD_HV_ADV</sub> external capacitance <sup>8</sup>   |                                          | —                                     | 1.5                | 3.3 | —   | μF   |

1 See Figure 6 for capacitor integration.

2 Recommended X7R or X5R ceramic low ESR capacitors, ±15% variation over voltage, temperature, and aging.

3 Each VDD\_LV pin requires both a 0.1μF and 0.01μF capacitor for high-frequency bypass and EMC requirements.

4 The typical CHV\_FL A bulk capacitance value is 1uF.

5 For noise filtering it is recommended to add a high frequency bypass capacitance of 0.1 μF between VDD\_HV\_PMC and VSS\_HV.

6 VDD\_HV\_PMC is shorted to VDD\_HV\_IO\_MAIN.

7 For noise filtering it is recommended to add a high frequency bypass capacitance of 0.1 μF between VDD\_HV\_ADV and VSS\_HV\_ADV.

### 3.9.3 3.3V flash supply

**Table 17. Flash power supply**

| Symbol       |    | Parameter                         | Conditions                                      | Value |     |     | Unit |
|--------------|----|-----------------------------------|-------------------------------------------------|-------|-----|-----|------|
|              |    |                                   |                                                 | Min   | Typ | Max |      |
| <sup>1</sup> | CC | Flash regulator DC output voltage | Before trimming                                 | 3.0   | 3.3 | 3.5 | V    |
|              |    |                                   | After trimming<br>−40°C ≤ T <sub>J</sub> ≤ 25°C | TBD   | 3.3 | TBD |      |

1 Min value accounts for all static and dynamic variations of the regulator (min cap as 0.75uF).

## 3.10 AC specifications

All AC timing specifications are valid up to 150 °C, except where explicitly noted.

### 3.10.1 Debug and calibration interface timing

#### 3.10.1.1 JTAG interface timing

Table 18. JTAG pin AC electrical characteristics<sup>1,2</sup>

| #  | Symbol               |    | Characteristic                                         | Value |                  | Unit |
|----|----------------------|----|--------------------------------------------------------|-------|------------------|------|
|    |                      |    |                                                        | Min   | Max              |      |
| 1  | $t_{JCYC}$           | CC | TCK cycle time                                         | 100   | —                | ns   |
| 2  | $t_{JDC}$            | CC | TCK clock pulse width                                  | 40    | 60               | %    |
| 3  | $t_{TCKRISE}$        | CC | TCK rise and fall times (40%–70%)                      | —     | 3                | ns   |
| 4  | $t_{TMSS}, t_{TDIS}$ | CC | TMS, TDI data setup time                               | 5     | —                | ns   |
| 5  | $t_{TMSH}, t_{TDIH}$ | CC | TMS, TDI data hold time                                | 5     | —                | ns   |
| 6  | $t_{TDOV}$           | CC | TCK low to TDO data valid                              | —     | 16 <sup>3</sup>  | ns   |
| 7  | $t_{TDOI}$           | CC | TCK low to TDO data invalid                            | 0     | —                | ns   |
| 8  | $t_{TDOHZ}$          | CC | TCK low to TDO high impedance                          | —     | 15               | ns   |
| 9  | $t_{JCMPPW}$         | CC | JCOMP assertion time                                   | 100   | —                | ns   |
| 10 | $t_{JCMPs}$          | CC | JCOMP setup time to TCK low                            | 40    | —                | ns   |
| 11 | $t_{BSDV}$           | CC | TCK falling edge to output valid                       | —     | 600 <sup>4</sup> | ns   |
| 12 | $t_{BSDVZ}$          | CC | TCK falling edge to output valid out of high impedance | —     | 600              | ns   |
| 13 | $t_{BSDHZ}$          | CC | TCK falling edge to output high impedance              | —     | 600              | ns   |
| 14 | $t_{BSDST}$          | CC | Boundary scan input valid to TCK rising edge           | 15    | —                | ns   |
| 15 | $t_{BSDHT}$          | CC | TCK rising edge to boundary scan input invalid         | 15    | —                | ns   |

<sup>1</sup> These specifications apply to JTAG boundary scan only. See [Table 18](#) for functional specifications.

<sup>2</sup> JTAG timing specified at  $V_{DD\_HV\_IO\_MAIN} = 4.0\text{ V}$  to  $5.5\text{ V}$ , and maximum loading per pad type as specified in the I/O section of the data sheet.

<sup>3</sup> Timing includes TCK pad delay, clock tree delay, logic delay and TDO output pad delay.

## Electrical characteristics

- <sup>4</sup> Applies to all pins, limited by pad slew rate. Refer to IO delay and transition specification and add 20 ns for JTAG delay.

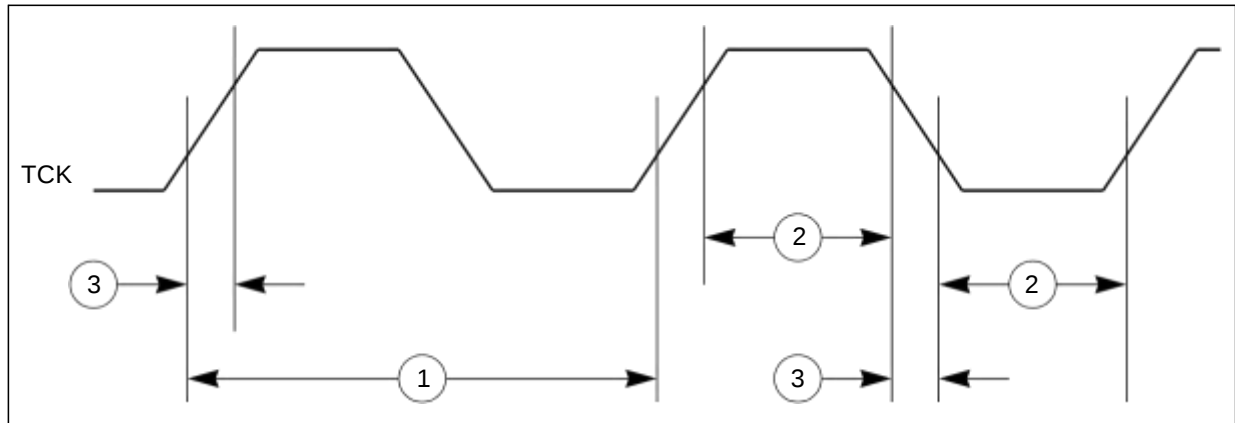


Figure 7. JTAG test clock input timing

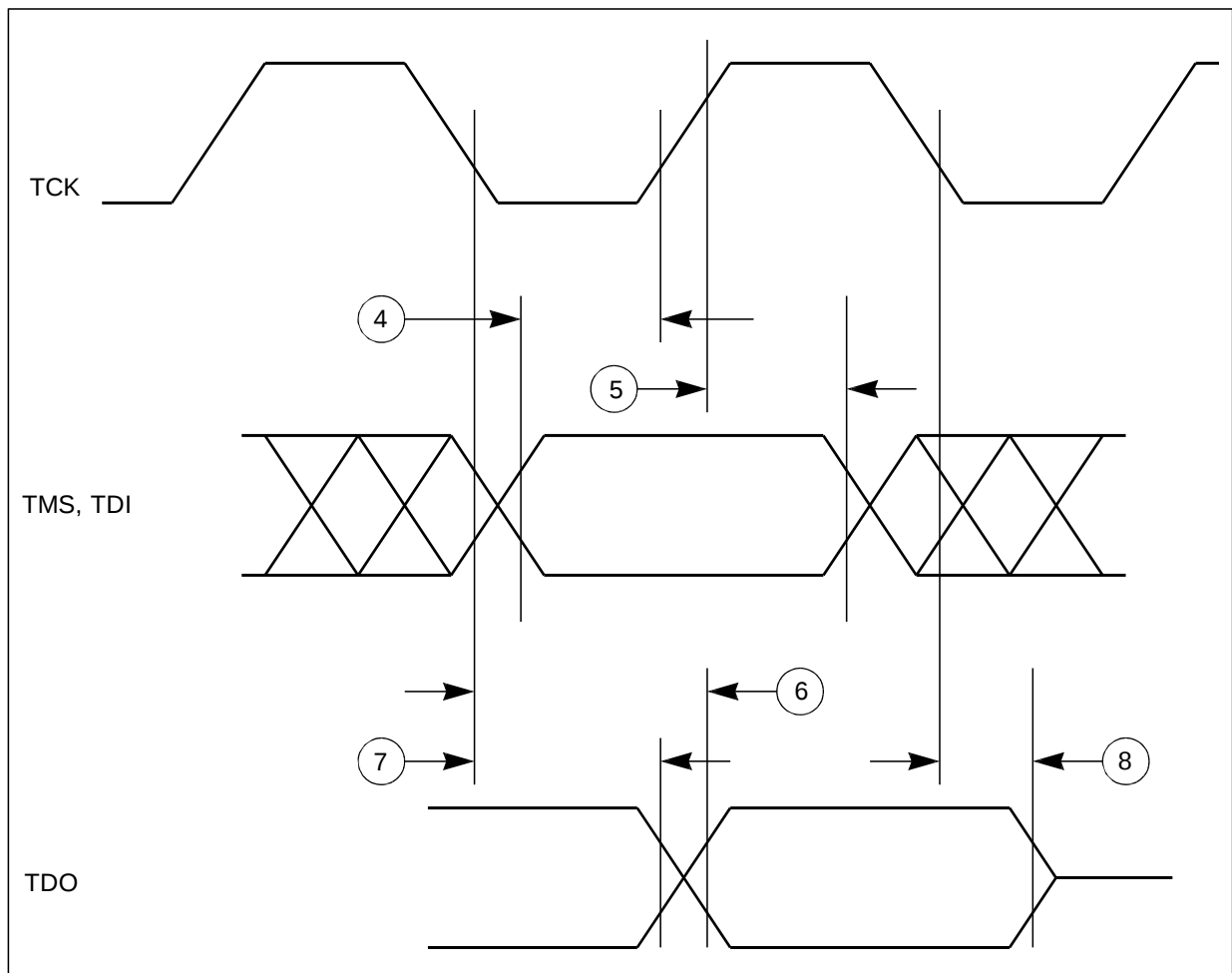


Figure8. JTAG test access port timing

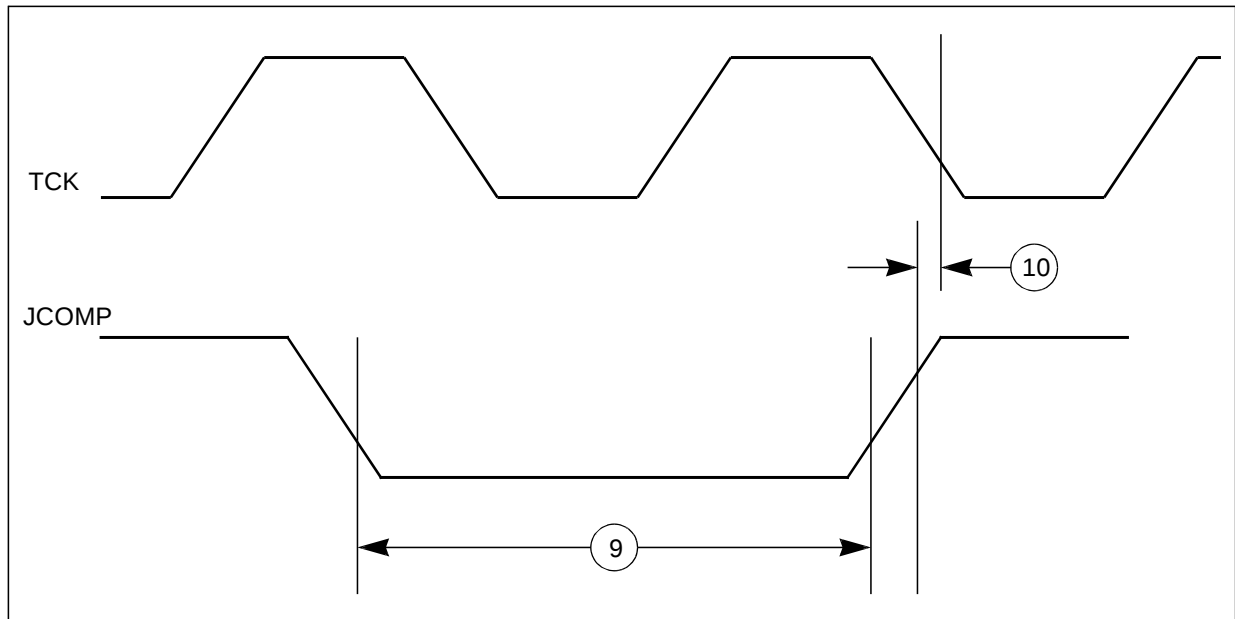


Figure 9. JTAG JCOMP timing

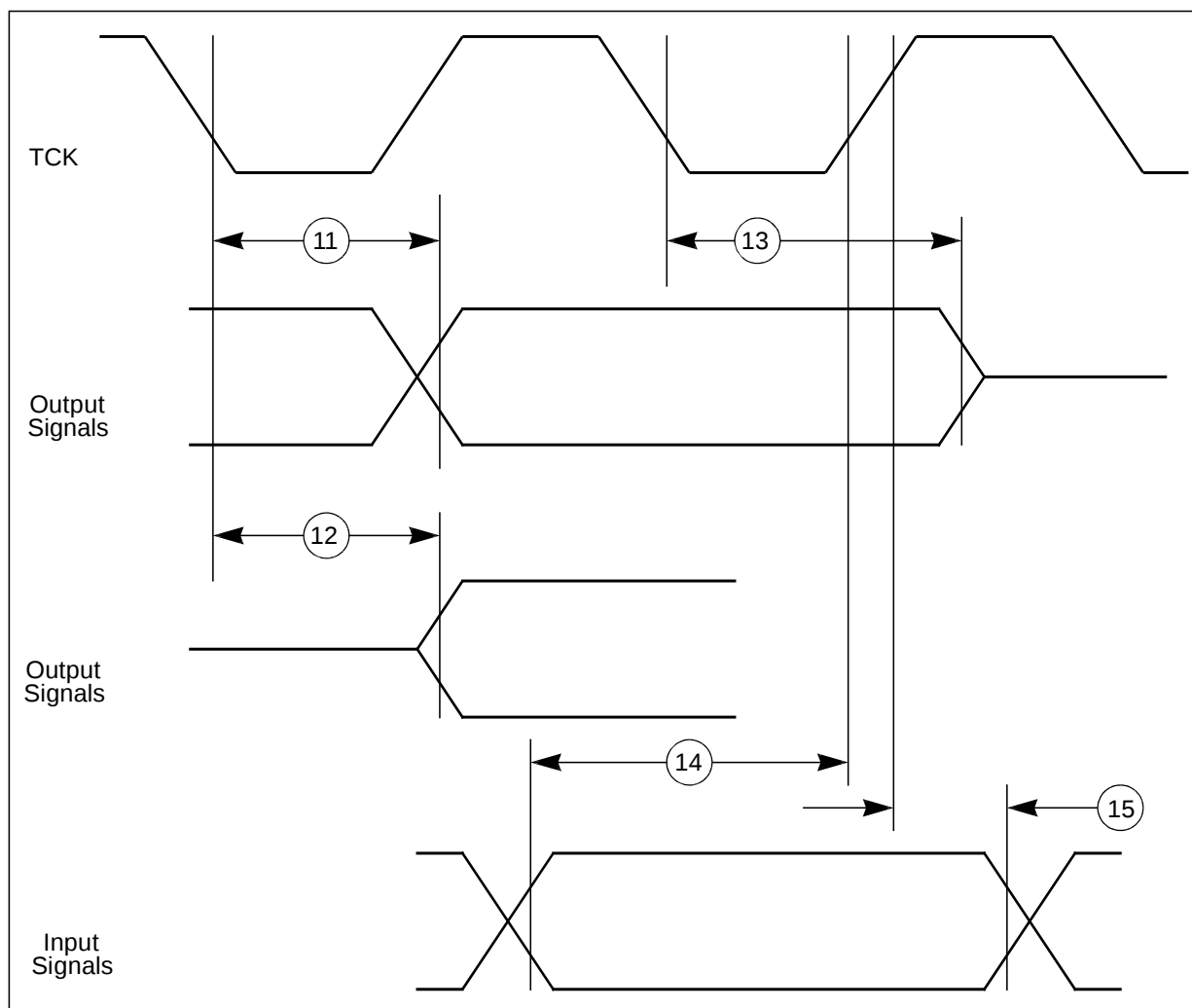


Figure 10. JTAG boundary scan timing



### 3.10.2 DSPI timing with CMOS and LVDS<sup>1</sup> pads

DSPI channel frequency support is shown in [Table 50](#). Timing specifications are shown in [Table 51](#), [Table 52](#), [Table 54](#), [Table 55](#) and [Table 56](#).

**Table 50. DSPI channel frequency support**

| DSPI use mode                   |                                                                                           | Max usable frequency (MHz) <sup>1,2</sup> |
|---------------------------------|-------------------------------------------------------------------------------------------|-------------------------------------------|
| CMOS (Master mode)              | Full duplex – Classic timing ( <a href="#">Table 19</a> )                                 | 17                                        |
|                                 | Full duplex – Modified timing ( <a href="#">Table 20</a> )                                | 30                                        |
|                                 | Output only mode (SCK/SOUT/PCS) ( <a href="#">Table 19</a> and <a href="#">Table 20</a> ) | 30                                        |
|                                 | Output only mode TSB mode (SCK/SOUT/PCS) ( <a href="#">Table 24</a> )                     | 30                                        |
| LVDS (Master mode) <sup>3</sup> | Full duplex – Modified timing ( <a href="#">Table 22</a> )                                | 33                                        |
|                                 | Output only mode TSB mode (SCK/SOUT/PCS) ( <a href="#">Table 23</a> )                     | 40                                        |

<sup>1</sup> Maximum usable frequency can be achieved if used with fastest configuration of the highest drive pads.

<sup>2</sup> Maximum usable frequency does not take into account external device propagation delay.

<sup>3</sup>  $\mu$ S Channel and LVDS timing is not supported for DSPI12.

#### 3.10.2.1 DSPI master mode full duplex timing with CMOS and LVDS pads

##### 3.10.2.1.1 DSPI CMOS Master Mode – Classic Timing

**Table 19. DSPI CMOS master classic timing (full duplex and output only) – MTFE = 0, CPHA = 0 or 1<sup>1</sup>**

| # | Symbol           |    | Characteristic   | Condition                  |                        | Value <sup>2</sup>                                     |     | Unit |
|---|------------------|----|------------------|----------------------------|------------------------|--------------------------------------------------------|-----|------|
|   |                  |    |                  | Pad drive <sup>3</sup>     | Load (C <sub>L</sub> ) | Min                                                    | Max |      |
| 1 | t <sub>SCK</sub> | CC | SCK cycle time   | SCK drive strength         |                        |                                                        |     | ns   |
|   |                  |    |                  | PAD3V5V = 0                | 25 pF                  | 33.0                                                   | —   |      |
|   |                  |    |                  | PAD3V5V = 0                | 50 pF                  | 80.0                                                   | —   |      |
| 2 | t <sub>CSC</sub> | CC | PCS to SCK delay | SCK and PCS drive strength |                        |                                                        |     | ns   |
|   |                  |    |                  | PAD3V5V = 0                | 25 pF                  | 5                                                      | —   |      |
|   |                  |    |                  | PAD3V5V = 0                | 50 pF                  | (N <sup>4</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 16 | —   |      |

1. DSPI in TSB mode with LVDS pads can be used to implement Micro Second Channel bus protocol.

Table 19. DSPI CMOS master classic timing (full duplex and output only) – MTFE = 0, CPHA = 0 or 1<sup>1</sup>

| #                                     | Symbol            |    | Characteristic                              | Condition                   |                           | Value <sup>2</sup>                                     |                                                  | Unit |
|---------------------------------------|-------------------|----|---------------------------------------------|-----------------------------|---------------------------|--------------------------------------------------------|--------------------------------------------------|------|
|                                       |                   |    |                                             | Pad drive <sup>3</sup>      | Load (C <sub>L</sub> )    | Min                                                    | Max                                              |      |
| 3                                     | t <sub>ASC</sub>  | CC | After SCK delay                             | SCK and PCS drive strength  |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | PCS = 0 pF<br>SCK = 50 pF | (M <sup>6</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 35 | —                                                | ns   |
|                                       |                   |    |                                             | PAD3V5V = 0                 | PCS = 0 pF<br>SCK = 50 pF | (M <sup>6</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 35 | —                                                |      |
| 4                                     | t <sub>SDC</sub>  | CC | SCK duty cycle <sup>7</sup>                 | SCK drive strength          |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 0 pF                      | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> – 2       | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 | ns   |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 0 pF                      | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> – 2       | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 |      |
| PCS strobe timing                     |                   |    |                                             |                             |                           |                                                        |                                                  |      |
| 5                                     | t <sub>PCSC</sub> | CC | PCSx to PCSS time <sup>8</sup>              | PCS and PCSS drive strength |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 25 pF                     | 16.0                                                   | —                                                | ns   |
| 6                                     | t <sub>PASC</sub> | CC | PCSS to PCSx time <sup>8</sup>              | PCS and PCSS drive strength |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 25 pF                     | 16.0                                                   | —                                                | ns   |
| SIN setup time                        |                   |    |                                             |                             |                           |                                                        |                                                  |      |
| 7                                     | t <sub>SUI</sub>  | CC | SIN setup time to SCK <sup>9</sup>          | SCK drive strength          |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 25 pF                     | 25.0                                                   | —                                                | ns   |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 50 pF                     | 32.75                                                  | —                                                |      |
| SIN hold time                         |                   |    |                                             |                             |                           |                                                        |                                                  |      |
| 8                                     | t <sub>HI</sub>   | CC | SIN hold time from SCK <sup>9</sup>         | SCK drive strength          |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 0 pF                      | –1.0                                                   | —                                                | ns   |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 0 pF                      | –1.0                                                   | —                                                |      |
| SOUT data valid time (after SCK edge) |                   |    |                                             |                             |                           |                                                        |                                                  |      |
| 9                                     | t <sub>SUO</sub>  | CC | SOUT data valid time from SCK <sup>10</sup> | SOUT and SCK drive strength |                           |                                                        |                                                  |      |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 25 pF                     | —                                                      | 7.0                                              | ns   |
|                                       |                   |    |                                             | PAD3V5V = 0                 | 50 pF                     | —                                                      | 8.0                                              |      |
| SOUT data hold time (after SCK edge)  |                   |    |                                             |                             |                           |                                                        |                                                  |      |

**Table 19. DSPI CMOS master classic timing (full duplex and output only) – MTFE = 0, CPHA = 0 or 1<sup>1</sup>**

| #  | Symbol          |    | Characteristic                              | Condition                   |                        | Value <sup>2</sup> |     | Unit |
|----|-----------------|----|---------------------------------------------|-----------------------------|------------------------|--------------------|-----|------|
|    |                 |    |                                             | Pad drive <sup>3</sup>      | Load (C <sub>L</sub> ) | Min                | Max |      |
| 10 | t <sub>HO</sub> | CC | SOUT data hold time after SCK <sup>10</sup> | SOUT and SCK drive strength |                        |                    |     | ns   |
|    |                 |    |                                             | PAD3V5V = 0                 | 25 pF                  | -7.7               | —   |      |
|    |                 |    |                                             | PAD3V5V = 0                 | 50 pF                  | -11.0              | —   |      |

<sup>1</sup> All output timing is worst case and includes the mismatching of rise and fall times of the output pads.

<sup>2</sup> All timing values for output signals in this table are measured to 50% of the output voltage.

<sup>3</sup> Timing is guaranteed to same drive capabilities for all signals, mixing of pad drives may reduce operating speeds and may cause incorrect operation.

<sup>4</sup> N is the number of clock cycles added to time between PCS assertion and SCK assertion and is software programmable using DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, N is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

<sup>5</sup> t<sub>SYS</sub> is the period of DSPI\_CLKn clock, the input clock to the DSPI module. Maximum frequency is 100 MHz (min t<sub>SYS</sub> = 10 ns).

<sup>6</sup> M is the number of clock cycles added to time between SCK negation and PCS negation and is software programmable using DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, M is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

<sup>7</sup> t<sub>SDC</sub> is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.

<sup>8</sup> PCSx and PCSS using same pad configuration.

<sup>9</sup> Input timing assumes an input slew rate of 1 ns (10% – 90%) and uses TTL / Automotive voltage thresholds.

<sup>10</sup> SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

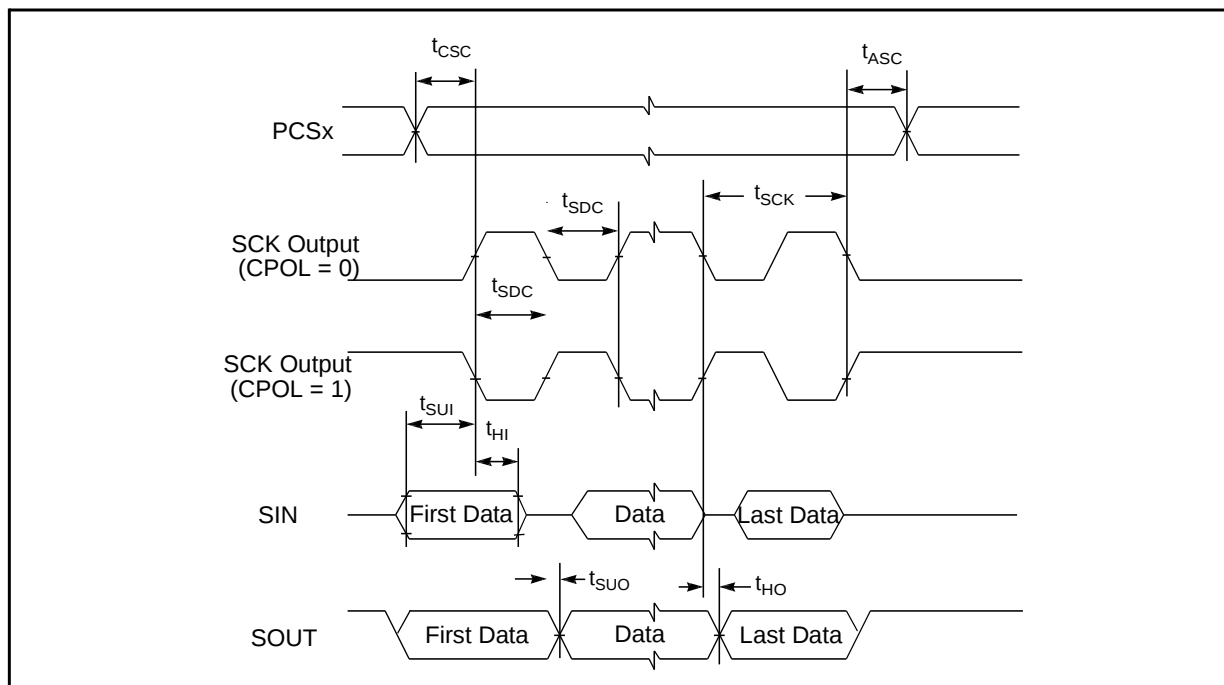


Figure 11. DSPI CMOS master mode – classic timing, CPHA = 0

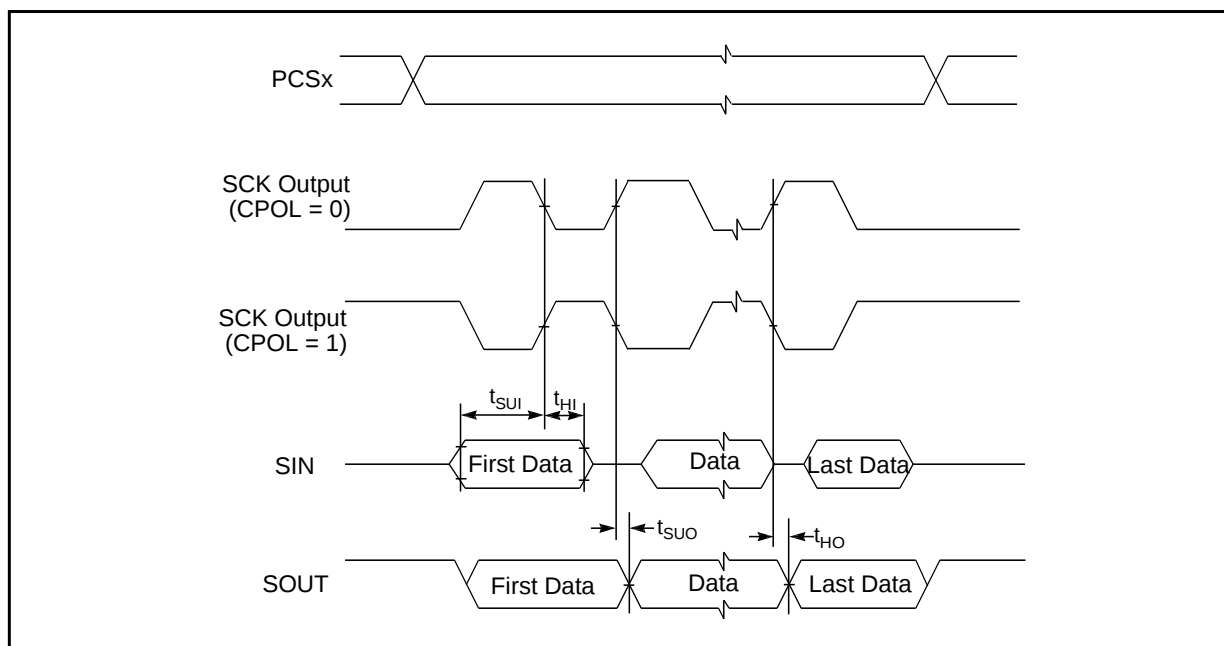


Figure 12. DSPI CMOS master mode – classic timing, CPHA = 1

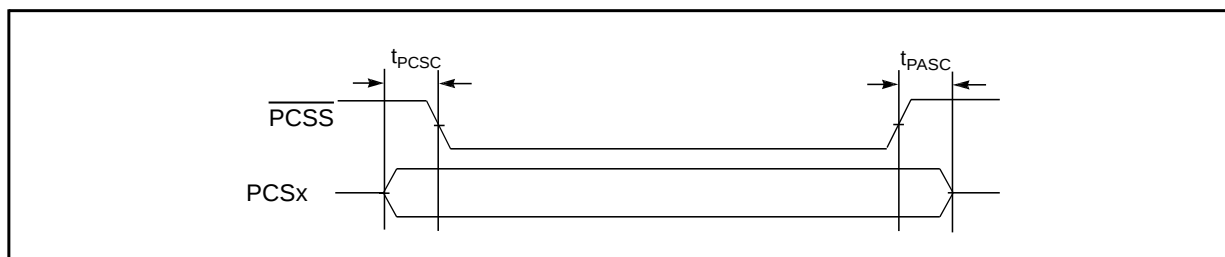


Figure 13. DSPI PCS strobe (PCSS) timing (master mode)

### 3.10.2.1.2 DSPI CMOS Master Mode – Modified Timing

Table 20. DSPI CMOS master modified timing (full duplex and output only) – MTFE = 1, CPHA = 0 or 1<sup>1</sup>

| #                 | Symbol           |    | Characteristic              | Condition                  |                           | Value <sup>2</sup>                                     |                                                  | Unit |
|-------------------|------------------|----|-----------------------------|----------------------------|---------------------------|--------------------------------------------------------|--------------------------------------------------|------|
|                   |                  |    |                             | Pad drive <sup>3</sup>     | Load (C <sub>L</sub> )    | Min                                                    | Max                                              |      |
| 1                 | t <sub>SCK</sub> | CC | SCK cycle time              | SCK drive strength         |                           |                                                        |                                                  | ns   |
|                   |                  |    |                             | PAD3V5V = 0                | 25 pF                     | 33.0                                                   | —                                                |      |
|                   |                  |    |                             | PAD3V5V = 0                | 50 pF                     | 80.0                                                   | —                                                |      |
| 2                 | t <sub>CSC</sub> | CC | PCS to SCK delay            | SCK and PCS drive strength |                           |                                                        |                                                  | ns   |
|                   |                  |    |                             | PAD3V5V = 0                | 25 pF                     | (N <sup>4</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 16 | —                                                |      |
|                   |                  |    |                             | PAD3V5V = 0                | 50 pF                     | (N <sup>4</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 16 | —                                                |      |
| 3                 | t <sub>ASC</sub> | CC | After SCK delay             | SCK and PCS drive strength |                           |                                                        |                                                  | ns   |
|                   |                  |    |                             | PAD3V5V = 0                | PCS = 0 pF<br>SCK = 50 pF | (M <sup>6</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 35 | —                                                |      |
|                   |                  |    |                             | PAD3V5V = 0                | PCS = 0 pF<br>SCK = 50 pF | (M <sup>6</sup> × t <sub>SYS</sub> <sup>5</sup> ) – 35 | —                                                |      |
| 4                 | t <sub>SDC</sub> | CC | SCK duty cycle <sup>7</sup> | SCK drive strength         |                           |                                                        |                                                  | ns   |
|                   |                  |    |                             | PAD3V5V = 0                | 0 pF                      | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> – 2       | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 |      |
|                   |                  |    |                             | PAD3V5V = 0                | 0 pF                      | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> – 2       | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 |      |
| PCS strobe timing |                  |    |                             |                            |                           |                                                        |                                                  |      |

Table 20. DSPI CMOS master modified timing (full duplex and output only) – MTFE = 1, CPHA = 0 or 1<sup>1</sup>

| #                                     | Symbol            |    | Characteristic                                       | Condition                   |                        | Value <sup>2</sup>                                        |                                    | Unit |
|---------------------------------------|-------------------|----|------------------------------------------------------|-----------------------------|------------------------|-----------------------------------------------------------|------------------------------------|------|
|                                       |                   |    |                                                      | Pad drive <sup>3</sup>      | Load (C <sub>L</sub> ) | Min                                                       | Max                                |      |
| 5                                     | t <sub>PCSC</sub> | CC | PCSx to PCSS time <sup>8</sup>                       | PCS and PCSS drive strength |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 25 pF                  | 16.0                                                      | —                                  |      |
| 6                                     | t <sub>PASC</sub> | CC | PCSS to PCSx time <sup>8</sup>                       | PCS and PCSS drive strength |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 25 pF                  | 16.0                                                      | —                                  |      |
| SIN setup time                        |                   |    |                                                      |                             |                        |                                                           |                                    |      |
| 7                                     | t <sub>SUI</sub>  | CC | SIN setup time to SCK CPHA = 0 <sup>9</sup>          | SCK drive strength          |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 25 pF                  | 25 – (P <sup>10</sup> × t <sub>SY</sub> <sup>5</sup> )    | —                                  |      |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 50 pF                  | 32.75 – (P <sup>10</sup> × t <sub>SY</sub> <sup>5</sup> ) | —                                  |      |
|                                       |                   |    | SIN setup time to SCK CPHA = 1 <sup>9</sup>          | SCK drive strength          |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 25 pF                  | 25.0                                                      | —                                  |      |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 50 pF                  | 32.75                                                     | —                                  |      |
| SIN hold time                         |                   |    |                                                      |                             |                        |                                                           |                                    |      |
| 8                                     | t <sub>HI</sub>   | CC | SIN hold time from SCK CPHA = 0 <sup>9</sup>         | SCK drive strength          |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 0 pF                   | –1 + (P <sup>9</sup> × t <sub>SY</sub> <sup>4</sup> )     | —                                  |      |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 0 pF                   | –1 + (P <sup>9</sup> × t <sub>SY</sub> <sup>4</sup> )     | —                                  |      |
|                                       |                   |    | SIN hold time from SCK CPHA = 1 <sup>9</sup>         | SCK drive strength          |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 0 pF                   | –1.0                                                      | —                                  |      |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 0 pF                   | –1.0                                                      | —                                  |      |
| SOUT data valid time (after SCK edge) |                   |    |                                                      |                             |                        |                                                           |                                    |      |
| 9                                     | t <sub>SUO</sub>  | CC | SOUT data valid time from SCK CPHA = 0 <sup>10</sup> | SOUT and SCK drive strength |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 25 pF                  | —                                                         | 7.0 + t <sub>SY</sub> <sup>5</sup> |      |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 50 pF                  | —                                                         | 8.0 + t <sub>SY</sub> <sup>5</sup> |      |
|                                       |                   |    | SOUT data valid time from SCK CPHA = 1 <sup>10</sup> | SOUT and SCK drive strength |                        |                                                           |                                    | ns   |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 25 pF                  | —                                                         | 7.0                                |      |
|                                       |                   |    |                                                      | PAD3V5V = 0                 | 50 pF                  | —                                                         | 8.0                                |      |
| SOUT data hold time (after SCK edge)  |                   |    |                                                      |                             |                        |                                                           |                                    |      |

**Table 20. DSPI CMOS master modified timing (full duplex and output only) – MTFE = 1, CPHA = 0 or 1<sup>1</sup>**

| #  | Symbol          |    | Characteristic                                          | Condition                   |                        | Value <sup>2</sup>                    |     | Unit |
|----|-----------------|----|---------------------------------------------------------|-----------------------------|------------------------|---------------------------------------|-----|------|
|    |                 |    |                                                         | Pad drive <sup>3</sup>      | Load (C <sub>L</sub> ) | Min                                   | Max |      |
| 10 | t <sub>HO</sub> | CC | SOUT data hold time after SCK<br>CPHA = 0 <sup>11</sup> | SOUT and SCK drive strength |                        |                                       |     | ns   |
|    |                 |    |                                                         | PAD3V5V = 0                 | 25 pF                  | -7.7 + t <sub>SYS</sub> <sup>5</sup>  | —   |      |
|    |                 |    |                                                         | PAD3V5V = 0                 | 50 pF                  | -11.0 + t <sub>SYS</sub> <sup>5</sup> | —   |      |
|    |                 |    | SOUT data hold time after SCK<br>CPHA = 1 <sup>11</sup> | SOUT and SCK drive strength |                        |                                       |     | ns   |
|    |                 |    |                                                         | PAD3V5V = 0                 | 25 pF                  | -7.7                                  | —   |      |
|    |                 |    |                                                         | PAD3V5V = 0                 | 50 pF                  | -11.0                                 | —   |      |

<sup>1</sup> All output timing is worst case and includes the mismatching of rise and fall times of the output pads.

<sup>2</sup> All timing values for output signals in this table are measured to 50% of the output voltage.

<sup>3</sup> Timing is guaranteed to same drive capabilities for all signals, mixing of pad drives may reduce operating speeds and may cause incorrect operation.

<sup>4</sup> N is the number of clock cycles added to time between PCS assertion and SCK assertion and is software programmable using DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, N is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

<sup>5</sup> t<sub>SYS</sub> is the period of DSPI\_CLKn clock, the input clock to the DSPI module. Maximum frequency is 100 MHz (min t<sub>SYS</sub> = 10 ns).

<sup>6</sup> M is the number of clock cycles added to time between SCK negation and PCS negation and is software programmable using DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, M is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

<sup>7</sup> t<sub>SDC</sub> is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.

<sup>8</sup> PCSx and PCSS using same pad configuration.

<sup>9</sup> Input timing assumes an input slew rate of 1 ns (10% – 90%) and uses TTL / Automotive voltage thresholds.

<sup>10</sup> P is the number of clock cycles added to delay the DSPI input sample point and is software programmable using DSPI\_MCR[SMPL\_PT]. The value must be 0, 1 or 2. If the baud rate divide ratio is /2 or /3, this value is automatically set to 1.

<sup>11</sup> SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

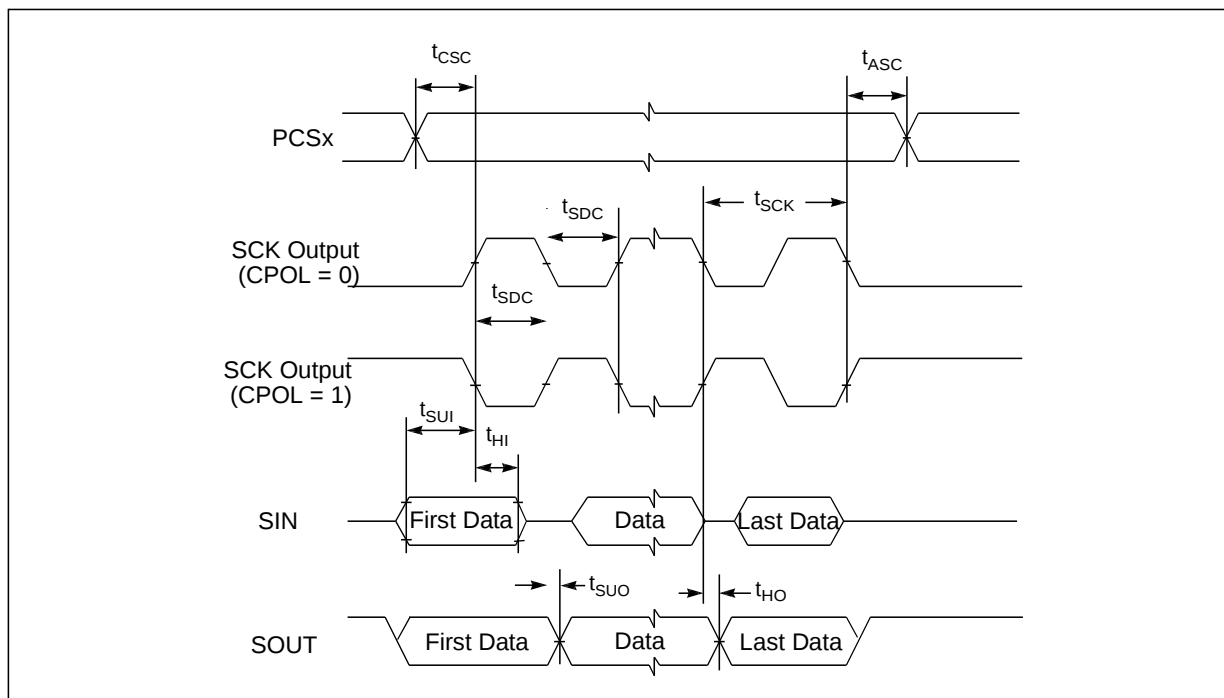


Figure 14. DSPI CMOS master mode – modified timing, CPHA = 0

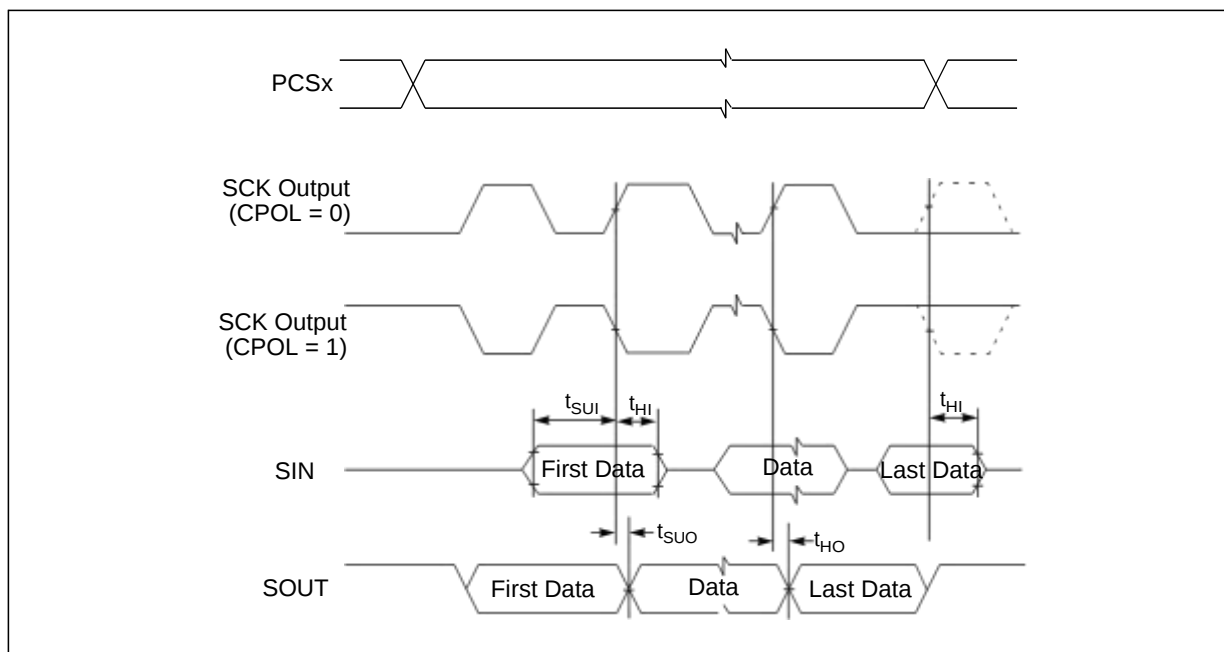


Figure 15. DSPI CMOS master mode – modified timing, CPHA = 1

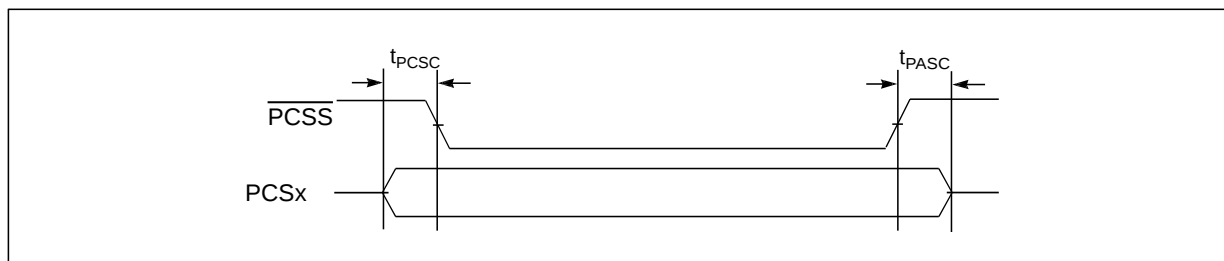


Figure 16. DSPI PCS strobe (PCSS) timing (master mode)

### 3.10.2.1.3 DSPI LVDS Master Mode – Modified Timing

Table 21. DSPI LVDS master timing – full duplex – modified transfer format (MTFE = 1), CPHA = 0 or 1

| # | Symbol    | Characteristic                 | Condition                                      |                             | Value <sup>1</sup>            |                          | Unit |
|---|-----------|--------------------------------|------------------------------------------------|-----------------------------|-------------------------------|--------------------------|------|
|   |           |                                | Pad drive                                      | Load                        | Min                           | Max                      |      |
| 1 | $t_{SCK}$ | CC SCK cycle time              | LVDS                                           | 15 pF to 25 pF differential | 30.0                          | —                        | ns   |
| 2 | $t_{CSC}$ | CC PCS to SCK delay (LVDS SCK) | PCS drive strength                             |                             |                               |                          |      |
|   |           |                                | PAD3V5V = 0                                    | 25 pF                       | $(N^2 \times t_{SYS}^3) - 10$ | —                        | ns   |
|   |           |                                | PAD3V5V = 0                                    | 50 pF                       | $(N^2 \times t_{SYS}^3) - 10$ | —                        | ns   |
| 3 | $t_{ASC}$ | CC After SCK delay (LVDS SCK)  | PAD3V5V = 0                                    | PCS = 0 pF<br>SCK = 25 pF   | $(M^4 \times t_{SYS}^3) - 8$  | —                        | ns   |
|   |           |                                | PAD3V5V = 0                                    | PCS = 0 pF<br>SCK = 25 pF   | $(M^4 \times t_{SYS}^3) - 8$  | —                        | ns   |
| 4 | $t_{SDC}$ | CC SCK duty cycle <sup>5</sup> | LVDS                                           | 15 pF to 25 pF differential | $\frac{1}{2}t_{SCK} - 2$      | $\frac{1}{2}t_{SCK} + 2$ | ns   |
| 7 | $t_{SUI}$ | CC                             | SIN setup time                                 |                             |                               |                          |      |
|   |           |                                | SIN setup time to SCK<br>CPHA = 0 <sup>6</sup> |                             |                               |                          |      |
|   |           |                                | LVDS                                           | 15 pF to 25 pF differential | $23 - (P^7 \times t_{SYS}^3)$ | —                        | ns   |
|   |           |                                | SIN setup time to SCK<br>CPHA = 1 <sup>6</sup> |                             |                               |                          |      |
|   |           |                                | LVDS                                           | 15 pF to 25 pF differential | 23                            | —                        | ns   |

Table 21. DSPI LVDS master timing – full duplex – modified transfer format (MTFE = 1), CPHA = 0 or 1

| #                                                      | Symbol                      | Characteristic              | Condition                                              |                             | Value <sup>1</sup>          |                                                        | Unit                                |    |
|--------------------------------------------------------|-----------------------------|-----------------------------|--------------------------------------------------------|-----------------------------|-----------------------------|--------------------------------------------------------|-------------------------------------|----|
|                                                        |                             |                             | Pad drive                                              | Load                        | Min                         | Max                                                    |                                     |    |
| 8                                                      | t <sub>HI</sub>             | CC                          | SIN Hold Time                                          |                             |                             |                                                        |                                     |    |
|                                                        |                             |                             | SIN hold time from SCK<br>CPHA = 0 <sup>6</sup>        | SCK drive strength          |                             |                                                        |                                     |    |
|                                                        |                             |                             |                                                        | LVDS                        | 0 pF differential           | -1 + (P <sup>7</sup> × t <sub>SYS</sub> <sup>3</sup> ) | —                                   | ns |
|                                                        |                             |                             | SIN hold time from SCK<br>CPHA = 1 <sup>6</sup>        | SCK drive strength          |                             |                                                        |                                     |    |
|                                                        |                             |                             |                                                        | LVDS                        | 0 pF differential           | -1                                                     | —                                   | ns |
| 9                                                      | t <sub>SUO</sub>            | CC                          | SOUT data valid time (after SCK edge)                  |                             |                             |                                                        |                                     |    |
|                                                        |                             |                             | SOUT data valid time from SCK<br>CPHA = 0 <sup>8</sup> | SOUT and SCK drive strength |                             |                                                        |                                     |    |
|                                                        |                             |                             |                                                        | LVDS                        | 15 pF to 25 pF differential | —                                                      | 7.0 + t <sub>SYS</sub> <sup>3</sup> | ns |
|                                                        |                             |                             | SOUT data valid time from SCK<br>CPHA = 1 <sup>8</sup> | SOUT and SCK drive strength |                             |                                                        |                                     |    |
|                                                        |                             |                             |                                                        | LVDS                        | 15 pF to 25 pF differential | —                                                      | 7.0                                 | ns |
|                                                        |                             |                             | 10                                                     | t <sub>HO</sub>             | CC                          | SOUT data hold time (after SCK edge)                   |                                     |    |
| SOUT data hold time after SCK<br>CPHA = 0 <sup>8</sup> | SOUT and SCK drive strength |                             |                                                        |                             |                             |                                                        |                                     |    |
|                                                        | LVDS                        | 15 pF to 25 pF differential |                                                        |                             |                             | -7.5 + t <sub>SYS</sub> <sup>3</sup>                   | —                                   | ns |
| SOUT data hold time after SCK<br>CPHA = 1 <sup>8</sup> | SOUT and SCK drive strength |                             |                                                        |                             |                             |                                                        |                                     |    |
|                                                        | LVDS                        | 15 pF to 25 pF differential |                                                        |                             |                             | -7.5                                                   | —                                   | ns |

<sup>1</sup> All timing values for output signals in this table are measured to 50% of the output voltage.

<sup>2</sup> N is the number of clock cycles added to time between PCS assertion and SCK assertion and is software programmable using DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, N is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

<sup>3</sup>  $t_{SYS}$  is the period of DSPI\_CLKn clock, the input clock to the DSPI module. Maximum frequency is 100 MHz (min  $t_{SYS} = 10$  ns).

<sup>4</sup> M is the number of clock cycles added to time between SCK negation and PCS negation and is software programmable using DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC]. The minimum value is 2 cycles unless TSB mode or Continuous SCK clock mode is selected, in which case, M is automatically set to 0 clock cycles (PCS and SCK are driven by the same edge of DSPI\_CLKn).

<sup>5</sup>  $t_{SDC}$  is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.

<sup>6</sup> Input timing assumes an input slew rate of 1 ns (10% – 90%) and LVDS differential voltage =  $\pm 100$  mV.

<sup>7</sup> P is the number of clock cycles added to delay the DSPI input sample point and is software programmable using DSPI\_MCR[SMPL\_PT]. The value must be 0, 1 or 2. If the baud rate divide ratio is /2 or /3, this value is automatically set to 1.

## Electrical characteristics

- <sup>8</sup> SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

**Table 22. DSPI LVDS slave timing – full duplex – modified transfer format (MTFE = 0/1)<sup>1</sup>**

| #  | Symbol    |    | Characteristic                                                   | Condition   |       | Value |     | Unit |
|----|-----------|----|------------------------------------------------------------------|-------------|-------|-------|-----|------|
|    |           |    |                                                                  | Pad drive   | Load  | Min   | Max |      |
| 1  | $t_{SCK}$ | CC | SCK cycle time <sup>2</sup>                                      | —           | —     | 62    | —   | ns   |
| 2  | $t_{CSC}$ | SR | SS to SCK delay <sup>2</sup>                                     | —           | —     | 16    | —   | ns   |
| 3  | $t_{ASC}$ | SR | SCK to SS delay <sup>2</sup>                                     | —           | —     | 16    | —   | ns   |
| 4  | $t_{SDC}$ | CC | SCK duty cycle <sup>2</sup>                                      | —           | —     | 30    | —   | ns   |
| 5  | $t_A$     | CC | Slave Access Time <sup>2, 3, 4</sup> (SS active to SOUT)         | PAD3V5V = 0 | 25 pF | —     | 50  | ns   |
|    |           |    |                                                                  | PAD3V5V = 0 | 50 pF | —     | 50  | ns   |
| 6  | $t_{DIS}$ | CC | Slave SOUT Disable Time <sup>2, 3, 4</sup> (SS inactive to SOUT) | PAD3V5V = 0 | 25 pF | —     | 5   | ns   |
|    |           |    |                                                                  | PAD3V5V = 0 | 50 pF | —     | 5   | ns   |
| 7  | $t_{SUI}$ | CC | Data setup time for inputs <sup>2</sup>                          | —           | —     | 10    | —   | ns   |
| 8  | $t_{HI}$  | CC | Data hold time for inputs <sup>2</sup>                           | —           | —     | 10    | —   | ns   |
| 9  | $t_{SUO}$ | CC | SOUT Valid Time <sup>2, 3, 4</sup> (after SCK edge)              | PAD3V5V = 0 | 25 pF | —     | 30  | ns   |
|    |           |    |                                                                  | PAD3V5V = 0 | 50 pF | —     | 30  | ns   |
| 10 | $t_{HO}$  | CC | SOUT Hold Time <sup>2, 3, 4</sup> (after SCK edge)               | PAD3V5V = 0 | 25 pF | 2.5   | —   | ns   |
|    |           |    |                                                                  | PAD3V5V = 0 | 50 pF | 2.5   | —   | ns   |

<sup>1</sup> DSPI slave operation is only supported for a single master and single slave on the device. Timing is valid for that case only.

<sup>2</sup> Input timing assumes an input slew rate of 1 ns (10% - 90%) and uses TTL / Automotive voltage thresholds.

<sup>3</sup> All timing values for output signals in this table, are measured to 50% of the output voltage.

<sup>4</sup> All output timing is worst case and includes the mismatching of rise and fall times of the output pads.

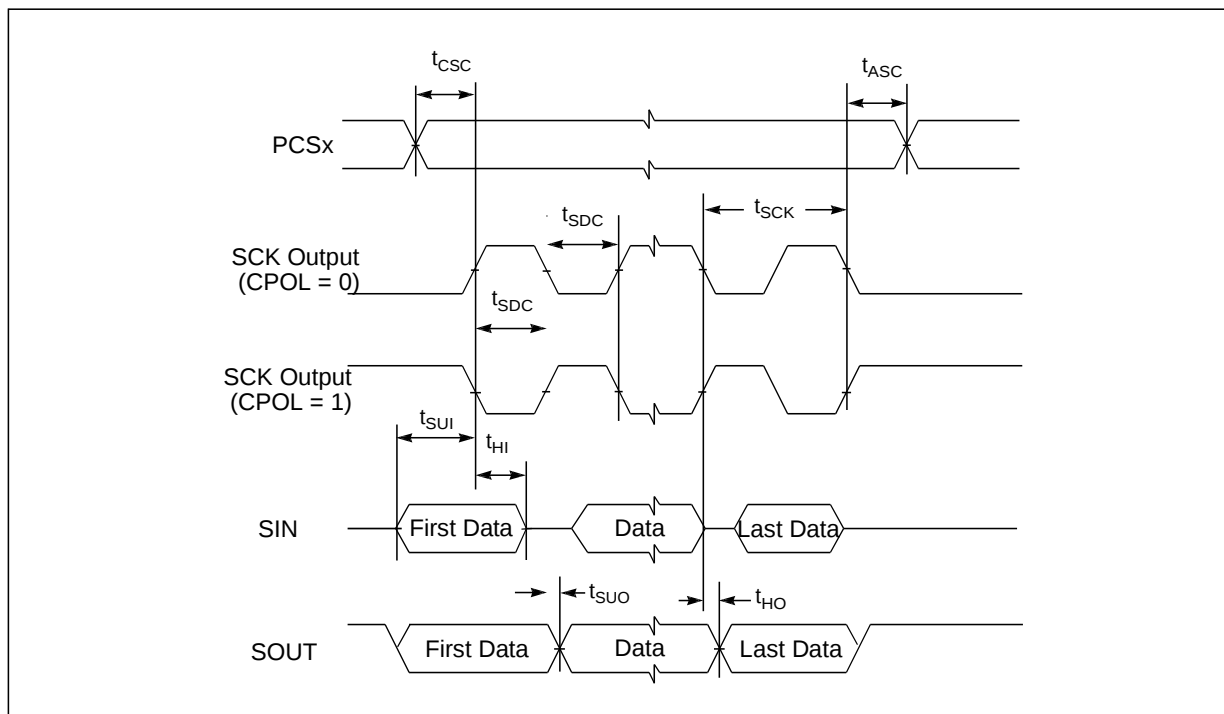


Figure 17. DSPI LVDS master mode – modified timing, CPHA = 0

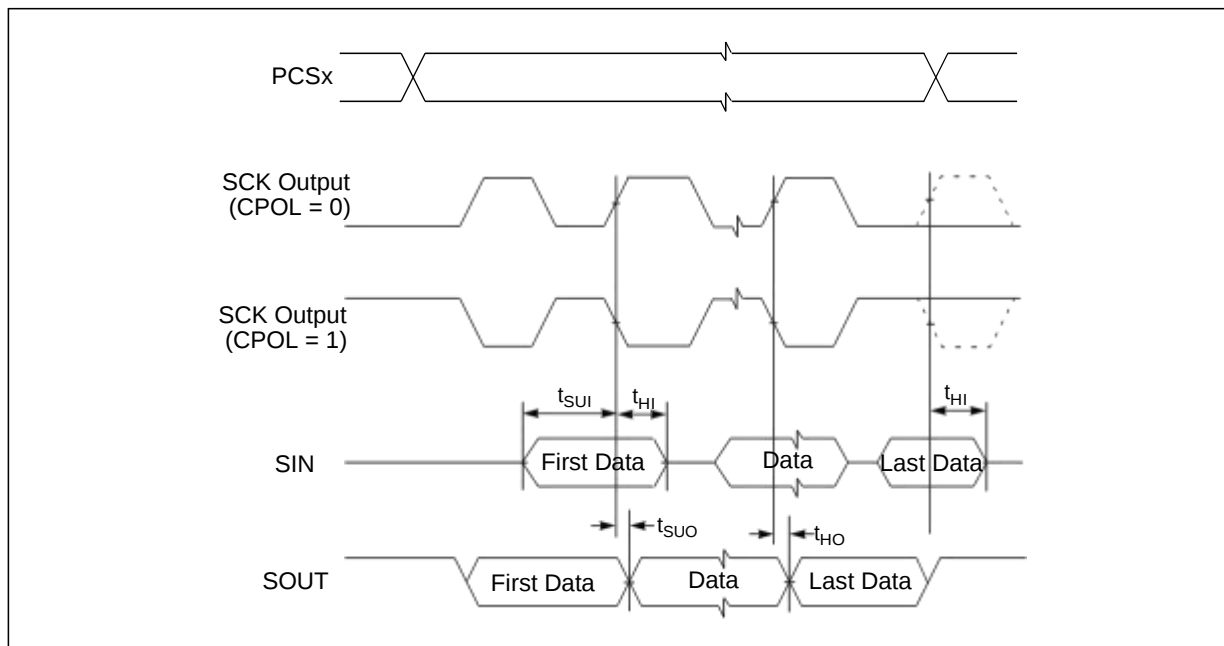


Figure 18. DSPI LVDS master mode – modified timing, CPHA = 1

## 3.10.2.1.4 DSPI Master Mode – Output Only

Table 23. DSPI LVDS master timing – output only – timed serial bus mode TSB = 1 or ITSB = 1, CPOL = 0 or 1, continuous SCK clock<sup>1,2</sup>

| #                                     | Symbol           |    | Characteristic                                                           | Condition                   |                             | Value                                            |                                                  | Unit |
|---------------------------------------|------------------|----|--------------------------------------------------------------------------|-----------------------------|-----------------------------|--------------------------------------------------|--------------------------------------------------|------|
|                                       |                  |    |                                                                          | Pad drive                   | Load                        | Min                                              | Max                                              |      |
| 1                                     | t <sub>SCK</sub> | CC | SCK cycle time                                                           | LVDS                        | 15 pF to 50 pF differential | 25.0                                             | —                                                | ns   |
| 2                                     | t <sub>CSV</sub> | CC | PCS valid after SCK <sup>3</sup> (SCK with 50 pF differential load cap.) | PAD3V5V = 0                 | 25 pF                       | —                                                | 6.0                                              | ns   |
|                                       |                  |    |                                                                          | PAD3V5V = 0                 | 50 pF                       | —                                                | 10.5                                             | ns   |
| 3                                     | t <sub>CSH</sub> | CC | PCS hold after SCK <sup>3</sup> (SCK with 50 pF differential load cap.)  | PAD3V5V = 0                 | 0 pF                        | −4.0                                             | —                                                | ns   |
|                                       |                  |    |                                                                          | PAD3V5V = 0                 | 0 pF                        | −4.0                                             | —                                                | ns   |
| 4                                     | t <sub>SDC</sub> | CC | SCK duty cycle (SCK with 50 pF differential load cap.)                   | LVDS                        | 15 pF to 50 pF differential | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> − 2 | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 | ns   |
| SOUT data valid time (after SCK edge) |                  |    |                                                                          |                             |                             |                                                  |                                                  |      |
| 5                                     | t <sub>SUO</sub> | CC | SOUT data valid time from SCK <sup>4</sup>                               | SOUT and SCK drive strength |                             |                                                  |                                                  |      |
|                                       |                  |    |                                                                          | LVDS                        | 15 pF to 50 pF differential | —                                                | 3.5                                              | ns   |
| SOUT data hold time (after SCK edge)  |                  |    |                                                                          |                             |                             |                                                  |                                                  |      |
| 6                                     | t <sub>HO</sub>  | CC | SOUT data hold time after SCK <sup>4</sup>                               | SOUT and SCK drive strength |                             |                                                  |                                                  |      |
|                                       |                  |    |                                                                          | LVDS                        | 15 pF to 50 pF differential | −3.5                                             | —                                                | ns   |

<sup>1</sup> All DSPI timing specifications apply to pins when using LVDS pads for SCK and SOUT and CMOS pad for PCS with pad driver strength as defined. Timing may degrade for weaker output drivers.

<sup>2</sup> TSB = 1 or ITSB = 1 automatically selects MTFE = 1 and CPHA = 1.

<sup>3</sup> With TSB mode or Continuous SCK clock mode selected, PCS and SCK are driven by the same edge of DSPI\_CLKn. This timing value is due to pad delays and signal propagation delays.

<sup>4</sup> SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

Table 24. DSPI CMOS master timing – output only – timed serial bus mode TSB = 1 or ITSB = 1, CPOL = 0 or 1, continuous SCK clock<sup>1,2</sup>

| # | Symbol           |    | Characteristic | Condition              |                        | Value <sup>3</sup> |     | Unit |
|---|------------------|----|----------------|------------------------|------------------------|--------------------|-----|------|
|   |                  |    |                | Pad drive <sup>4</sup> | Load (C <sub>L</sub> ) | Min                | Max |      |
| 1 | t <sub>SCK</sub> | CC | SCK cycle time | SCK drive strength     |                        |                    |     |      |
|   |                  |    |                | PAD3V5V = 0            | 25 pF                  | 33.0               | —   | ns   |
|   |                  |    |                | PAD3V5V = 0            | 50 pF                  | 80.0               | —   | ns   |

**Table 24. DSPI CMOS master timing – output only – timed serial bus mode TSB = 1 or ITSB = 1, CPOL = 0 or 1, continuous SCK clock<sup>1,2</sup> (continued)**

| #                                     | Symbol           |    | Characteristic                                         | Condition                   |                           | Value <sup>3</sup>                               |                                                  | Unit |
|---------------------------------------|------------------|----|--------------------------------------------------------|-----------------------------|---------------------------|--------------------------------------------------|--------------------------------------------------|------|
|                                       |                  |    |                                                        | Pad drive <sup>4</sup>      | Load (C <sub>L</sub> )    | Min                                              | Max                                              |      |
| 2                                     | t <sub>CSV</sub> | CC | PCS valid after SCK <sup>5</sup>                       | SCK and PCS drive strength  |                           |                                                  |                                                  |      |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 25 pF                     | 7                                                | —                                                | ns   |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 50 pF                     | 8                                                | —                                                | ns   |
| 3                                     | t <sub>CSH</sub> | CC | PCS hold after SCK <sup>5</sup>                        | SCK and PCS drive strength  |                           |                                                  |                                                  |      |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | PCS = 0 pF<br>SCK = 50 pF | –14                                              | —                                                | ns   |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | PCS = 0 pF<br>SCK = 50 pF | –14                                              | —                                                | ns   |
| 4                                     | t <sub>SDC</sub> | CC | SCK duty cycle <sup>6</sup>                            | SCK drive strength          |                           |                                                  |                                                  |      |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 0 pF                      | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> – 2 | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 | ns   |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 0 pF                      | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> – 2 | <sup>1</sup> / <sub>2</sub> t <sub>SCK</sub> + 2 | ns   |
| SOUT data valid time (after SCK edge) |                  |    |                                                        |                             |                           |                                                  |                                                  |      |
| 9                                     | t <sub>SUO</sub> | CC | SOUT data valid time from SCK<br>CPHA = 1 <sup>7</sup> | SOUT and SCK drive strength |                           |                                                  |                                                  |      |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 25 pF                     | —                                                | 7.0                                              | ns   |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 50 pF                     | —                                                | 8.0                                              | ns   |
| SOUT data hold time (after SCK edge)  |                  |    |                                                        |                             |                           |                                                  |                                                  |      |
| 10                                    | t <sub>HO</sub>  | CC | SOUT data hold time after SCK<br>CPHA = 1 <sup>7</sup> | SOUT and SCK drive strength |                           |                                                  |                                                  |      |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 25 pF                     | –7.7                                             | —                                                | ns   |
|                                       |                  |    |                                                        | PAD3V5V = 0                 | 50 pF                     | –11.0                                            | —                                                | ns   |

<sup>1</sup> TSB = 1 or ITSB = 1 automatically selects MTFE = 1 and CPHA = 1.

<sup>2</sup> All output timing is worst case and includes the mismatching of rise and fall times of the output pads.

<sup>3</sup> All timing values for output signals in this table are measured to 50% of the output voltage.

<sup>4</sup> Timing is guaranteed to same drive capabilities for all signals, mixing of pad drives may reduce operating speeds and may cause incorrect operation.

<sup>5</sup> With TSB mode or Continuous SCK clock mode selected, PCS and SCK are driven by the same edge of DSPI\_CLKn. This timing value is due to pad delays and signal propagation delays.

## Electrical characteristics

- <sup>6</sup>  $t_{SDC}$  is only valid for even divide ratios. For odd divide ratios the fundamental duty cycle is not 50:50. For these odd divide ratios cases, the absolute spec number is applied as jitter/uncertainty to the nominal high time and low time.
- <sup>7</sup> SOUT Data Valid and Data hold are independent of load capacitance if SCK and SOUT load capacitances are the same value.

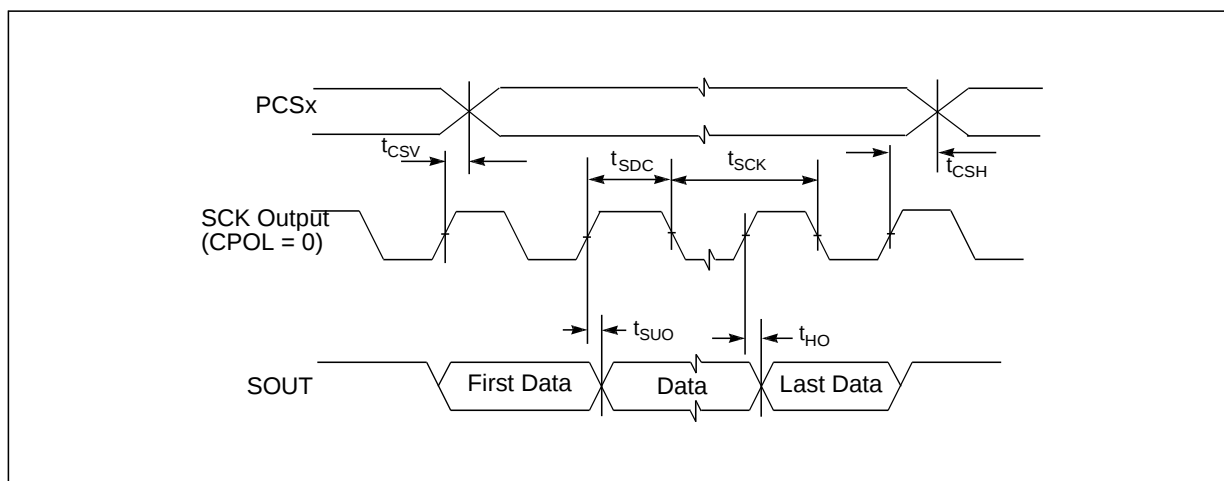


Figure 19. DSPI LVDS and CMOS master timing – output only – modified transfer format MTFE = 1, CHPA = 1

### 3.10.2.2 Slave Mode timing

Table 25. DSPI CMOS Slave timing - Modified Transfer Format (MTFE = 0/1)<sup>1</sup>

| #  | Symbol    | Characteristic                                                              | Condition   |       | Min | Max | Unit |
|----|-----------|-----------------------------------------------------------------------------|-------------|-------|-----|-----|------|
|    |           |                                                                             | Pad Drive   | Load  |     |     |      |
| 1  | $t_{SCK}$ | CC SCK Cycle Time <sup>2</sup>                                              | -           | -     | 62  | —   | ns   |
| 2  | $t_{CSC}$ | SR SS to SCK Delay <sup>2</sup>                                             | -           | -     | 16  | —   | ns   |
| 3  | $t_{ASC}$ | SR SCK to SS Delay <sup>2</sup>                                             | -           | -     | 16  | —   | ns   |
| 4  | $t_{SDC}$ | CC SCK Duty Cycle <sup>2</sup>                                              | -           | -     | 30  | —   | ns   |
| 5  | $t_A$     | CC Slave Access Time <sup>2,3,4</sup><br>(SS active to SOUT driven)         | PAD3V5V = 0 | 25 pF | —   | 50  | ns   |
|    |           |                                                                             | PAD3V5V = 0 | 50 pF | —   | 50  | ns   |
| 6  | $t_{DIS}$ | CC Slave SOUT Disable Time <sup>2,3,4</sup><br>(SS inactive to SOUT High-Z) | PAD3V5V = 0 | 25 pF | —   | 5   | ns   |
|    |           |                                                                             | PAD3V5V = 0 | 50 pF | —   | 5   | ns   |
| 9  | $t_{SUI}$ | CC Data Setup Time for Inputs <sup>2</sup>                                  | —           | —     | 10  | —   | ns   |
| 10 | $t_{HI}$  | CC Data Hold Time for Inputs <sup>2</sup>                                   | —           | —     | 10  | —   | ns   |

**Table 25. DSPI CMOS Slave timing - Modified Transfer Format (MTFE = 0/1)<sup>1</sup>**

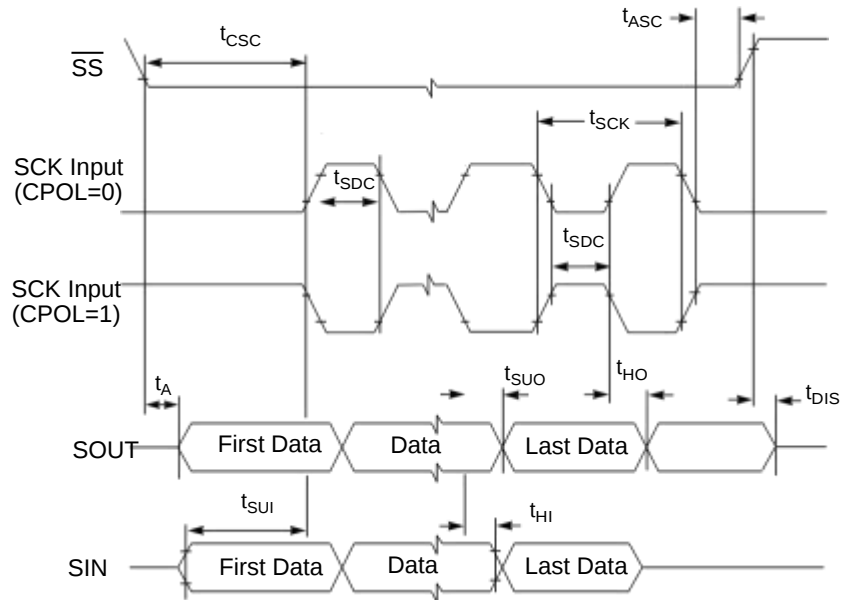
| #  | Symbol           | Characteristic                                       | Condition   |       | Min | Max | Unit |
|----|------------------|------------------------------------------------------|-------------|-------|-----|-----|------|
|    |                  |                                                      | Pad Drive   | Load  |     |     |      |
| 11 | $t_{\text{SUO}}$ | SOUT Valid Time <sup>2,3,4</sup><br>(after SCK edge) | PAD3V5V = 0 | 25 pF | —   | 30  | ns   |
|    |                  |                                                      | PAD3V5V = 0 | 50 pF | —   | 30  | ns   |
| 12 | $t_{\text{HO}}$  | SOUT Hold Time <sup>2,3,4</sup><br>(after SCK edge)  | PAD3V5V = 0 | 25 pF | 2.5 | —   | ns   |
|    |                  |                                                      | PAD3V5V = 0 | 50 pF | 2.5 | —   | ns   |

<sup>1</sup> DSPI slave operation is only supported for a single master and single slave on the device. Timing is valid for that case only.

<sup>2</sup> Input timing assumes an input slew rate of 1 ns (10% - 90%) and uses TTL / Automotive voltage thresholds.

<sup>3</sup> All timing values for output signals in this table, are measured to 50% of the output voltage.

<sup>4</sup> All output timing is worst case and includes the mismatching of rise and fall times of the output pads.

**Figure 20. DSPI Slave Mode - Modified transfer format timing (MFTE = 0/1) — CPHA = 0**

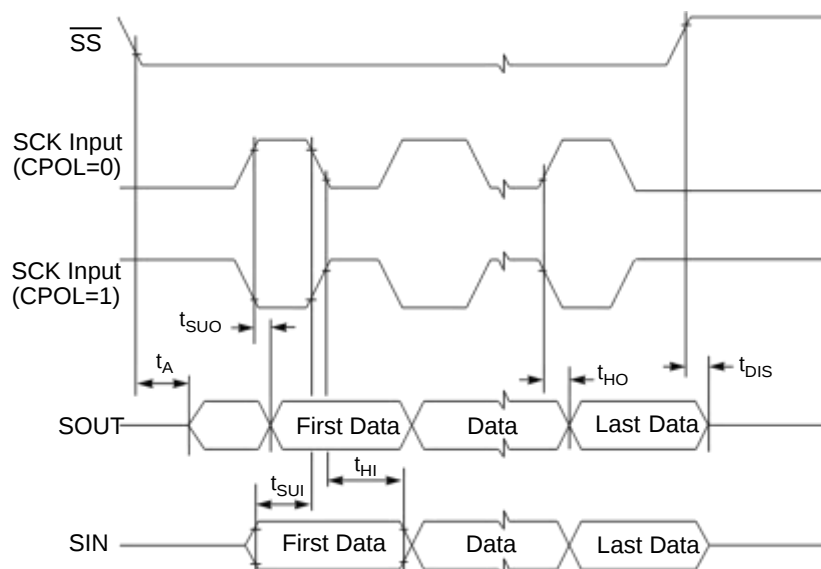


Figure 21. DSPI Slave Mode - Modified transfer format timing (MFTE = 0/1) — CPHA = 1

### 3.10.3 FEC timing

The FEC provides both MII and RMII interfaces in the 416 TEPBGA and 512 TEPBGA packages, and the MII and RMII signals can be configured for either CMOS or TTL signal levels compatible with devices operating at either 5.0 V or 3.3 V.

#### 3.10.3.1 MII receive signal timing (RXD[3:0], RX\_DV, RX\_ER, and RX\_CLK)

The receiver functions correctly up to a RX\_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the RX\_CLK frequency.

Table 26. MII receive signal timing<sup>1</sup>

| Symbol |    | Characteristic                         | Value |     | Unit          |
|--------|----|----------------------------------------|-------|-----|---------------|
|        |    |                                        | Min   | Max |               |
| M1     | CC | RXD[3:0], RX_DV, RX_ER to RX_CLK setup | 5     | —   | ns            |
| M2     | CC | RX_CLK to RXD[3:0], RX_DV, RX_ER hold  | 5     | —   | ns            |
| M3     | CC | RX_CLK pulse width high                | 35%   | 65% | RX_CLK period |
| M4     | CC | RX_CLK pulse width low                 | 35%   | 65% | RX_CLK period |

<sup>1</sup> All timing specifications are referenced from RX\_CLK = 1.4 V to the valid input levels, 0.8 V and 2.0 V.

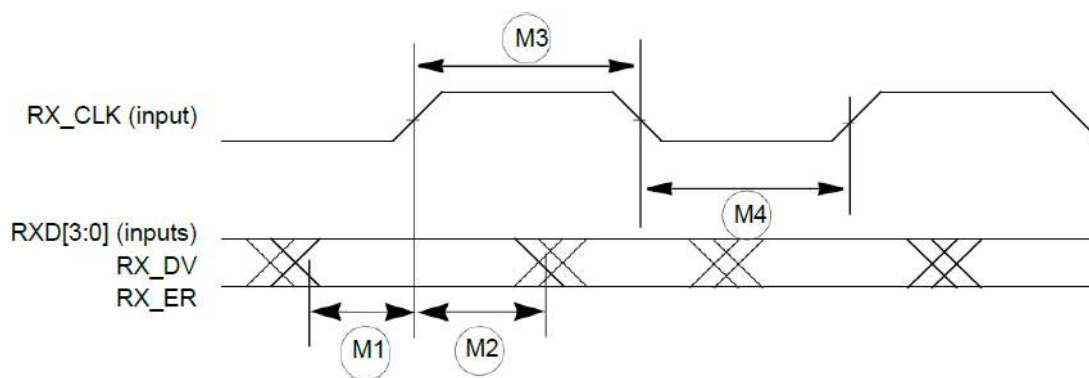


Figure 22. MII receive signal timing diagram

### 3.10.3.2 MII transmit signal timing (TXD[3:0], TX\_EN, TX\_ER, TX\_CLK)

The transmitter functions correctly up to a TX\_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the TX\_CLK frequency.

The transmit outputs (TXD[3:0], TX\_EN, TX\_ER) can be programmed to transition from either the rising or falling edge of TX\_CLK, and the timing is the same in either case. This options allows the use of non-compliant MII PHYs.

Refer to the *CCFC3007PT Microcontroller Reference Manual*'s Fast Ethernet Controller (FEC) chapter for details of this option and how to enable it.

Table 27. MII transmit signal timing<sup>1</sup>

| Symbol |    | Characteristic                           | Value <sup>2</sup> |     | Unit          |
|--------|----|------------------------------------------|--------------------|-----|---------------|
|        |    |                                          | Min                | Max |               |
| M5     | CC | TX_CLK to TXD[3:0], TX_EN, TX_ER invalid | 5                  | —   | ns            |
| M6     | CC | TX_CLK to TXD[3:0], TX_EN, TX_ER valid   | —                  | 25  | ns            |
| M7     | CC | TX_CLK pulse width high                  | 35%                | 65% | TX_CLK period |
| M8     | CC | TX_CLK pulse width low                   | 35%                | 65% | TX_CLK period |

<sup>1</sup> All timing specifications are referenced from TX\_CLK = 1.4 V to the valid output levels, 0.8 V and 2.0 V.

<sup>2</sup> Output parameters are valid for  $C_L = 25$  pF, where  $C_L$  is the external load to the device. The internal package capacitance is accounted for, and does not need to be subtracted from the 25 pF value.

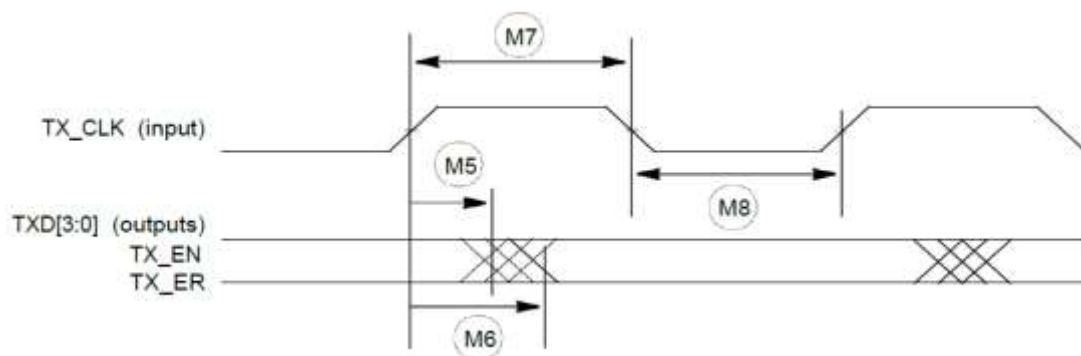


Figure 23. MII transmit signal timing diagram

### 3.10.3.3 MII async inputs signal timing (CRS and COL)

Table 28. MII async inputs signal timing

| Symbol | Characteristic                  | Value |     | Unit          |
|--------|---------------------------------|-------|-----|---------------|
|        |                                 | Min   | Max |               |
| M9     | CC CRS, COL minimum pulse width | 1.5   | —   | TX_CLK period |



Figure 24. MII async inputs timing diagram

### 3.10.3.4 MII and RMII serial management channel timing (MDIO and MDC)

The FEC functions correctly with a maximum MDC frequency of 2.5 MHz.

Table 29. MII serial management channel timing<sup>1</sup>

| Symbol | Characteristic                                                         | Value <sup>2</sup> |     | Unit       |
|--------|------------------------------------------------------------------------|--------------------|-----|------------|
|        |                                                                        | Min                | Max |            |
| M10    | CC MDC falling edge to MDIO output invalid (minimum propagation delay) | 0                  | —   | ns         |
| M11    | CC MDC falling edge to MDIO output valid (max prop delay)              | —                  | 25  | ns         |
| M12    | CC MDIO (input) to MDC rising edge setup                               | 10                 | —   | ns         |
| M13    | CC MDIO (input) to MDC rising edge hold                                | 0                  | —   | ns         |
| M14    | CC MDC pulse width high                                                | 40%                | 60% | MDC period |
| M15    | CC MDC pulse width low                                                 | 40%                | 60% | MDC period |

<sup>1</sup> All timing specifications are referenced from MDC = 1.4 V (TTL levels) to the valid input and output levels, 0.8 V and 2.0 V (TTL levels). For 5 V operation, timing is referenced from MDC = 50% to 2.2 V/3.5 V input and output levels.

- <sup>2</sup> Output parameters are valid for  $C_L = 25$  pF, where  $C_L$  is the external load to the device. The internal package capacitance is accounted for, and does not need to be subtracted from the 25 pF value.

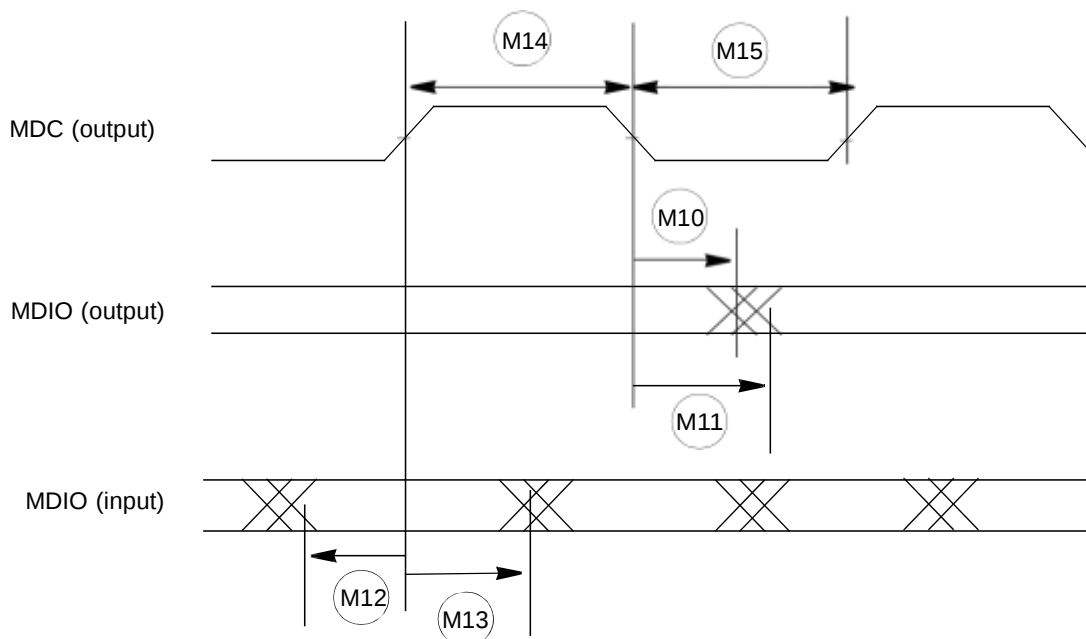


Figure 25. MII serial management channel timing diagram

### 3.10.3.5 RMII receive signal timing (RXD[1:0], CRS\_DV)

The receiver functions correctly up to a REF\_CLK maximum frequency of 50 MHz +1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the RX\_CLK frequency, which is half that of the REF\_CLK frequency.

Table 30. RMII receive signal timing<sup>1</sup>

| Symbol |    | Characteristic                    | Value |     | Unit           |
|--------|----|-----------------------------------|-------|-----|----------------|
|        |    |                                   | Min   | Max |                |
| R1     | CC | RXD[1:0], CRS_DV to REF_CLK setup | 4     | —   | ns             |
| R2     | CC | REF_CLK to RXD[1:0], CRS_DV hold  | 2     | —   | ns             |
| R3     | CC | REF_CLK pulse width high          | 35%   | 65% | REF_CLK period |
| R4     | CC | REF_CLK pulse width low           | 35%   | 65% | REF_CLK period |

<sup>1</sup> All timing specifications are referenced from REF\_CLK = 1.4 V to the valid input levels, 0.8 V and 2.0 V.

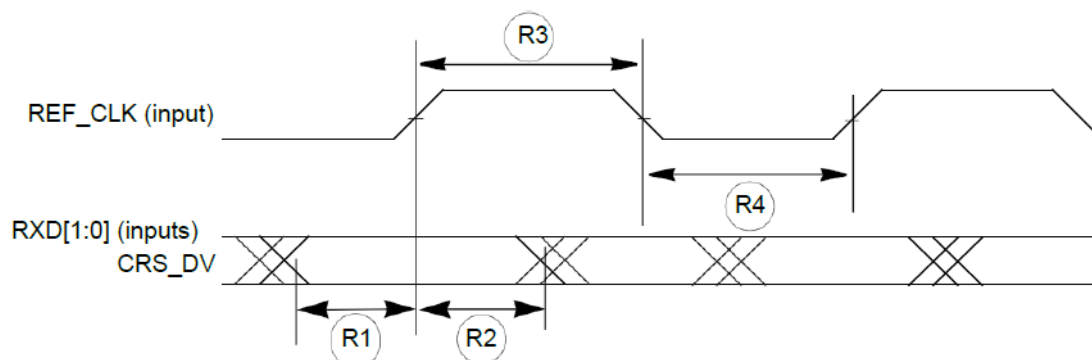


Figure 26. RMII receive signal timing diagram

### 3.10.3.6 RMII transmit signal timing (TXD[1:0], TX\_EN)

The transmitter functions correctly up to a REF\_CLK maximum frequency of 50 MHz + 1%. There is no minimum frequency requirement. The system clock frequency must be at least equal to or greater than the TX\_CLK frequency, which is half that of the REF\_CLK frequency.

The transmit outputs (TXD[1:0], TX\_EN) can be programmed to transition from either the rising or falling edge of REF\_CLK, and the timing is the same in either case. These options allows the use of non-compliant RMII PHYs.

Table 31. RMII transmit signal timing<sup>1, 2</sup>

| Symbol |    | Characteristic                     | Value <sup>3</sup> |     | Unit           |
|--------|----|------------------------------------|--------------------|-----|----------------|
|        |    |                                    | Min                | Max |                |
| R5     | CC | REF_CLK to TXD[1:0], TX_EN invalid | 2                  | —   | ns             |
| R6     | CC | REF_CLK to TXD[1:0], TX_EN valid   | —                  | 16  | ns             |
| R7     | CC | REF_CLK pulse width high           | 35%                | 65% | REF_CLK period |
| R8     | CC | REF_CLK pulse width low            | 35%                | 65% | REF_CLK period |

<sup>1</sup> RMII timing is valid only up to a maximum of 150 °C junction temperature.

<sup>2</sup> All timing specifications are referenced for TTL or CMOS input levels for REF\_CLK to the valid output levels, 0.8 V and 2.0 V.

<sup>3</sup> Output parameters are valid for  $C_L = 25$  pF, where  $C_L$  is the external load to the device. The internal package capacitance is accounted for, and does not need to be subtracted from the 25 pF value.

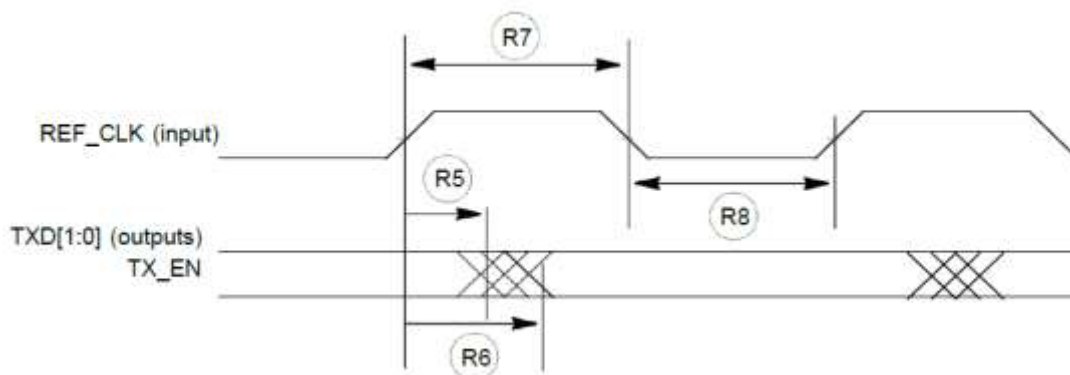


Figure 27. RMII transmit signal timing diagram

## 4 Package Information

### 4.1 416 TEPBGA (production) case drawing

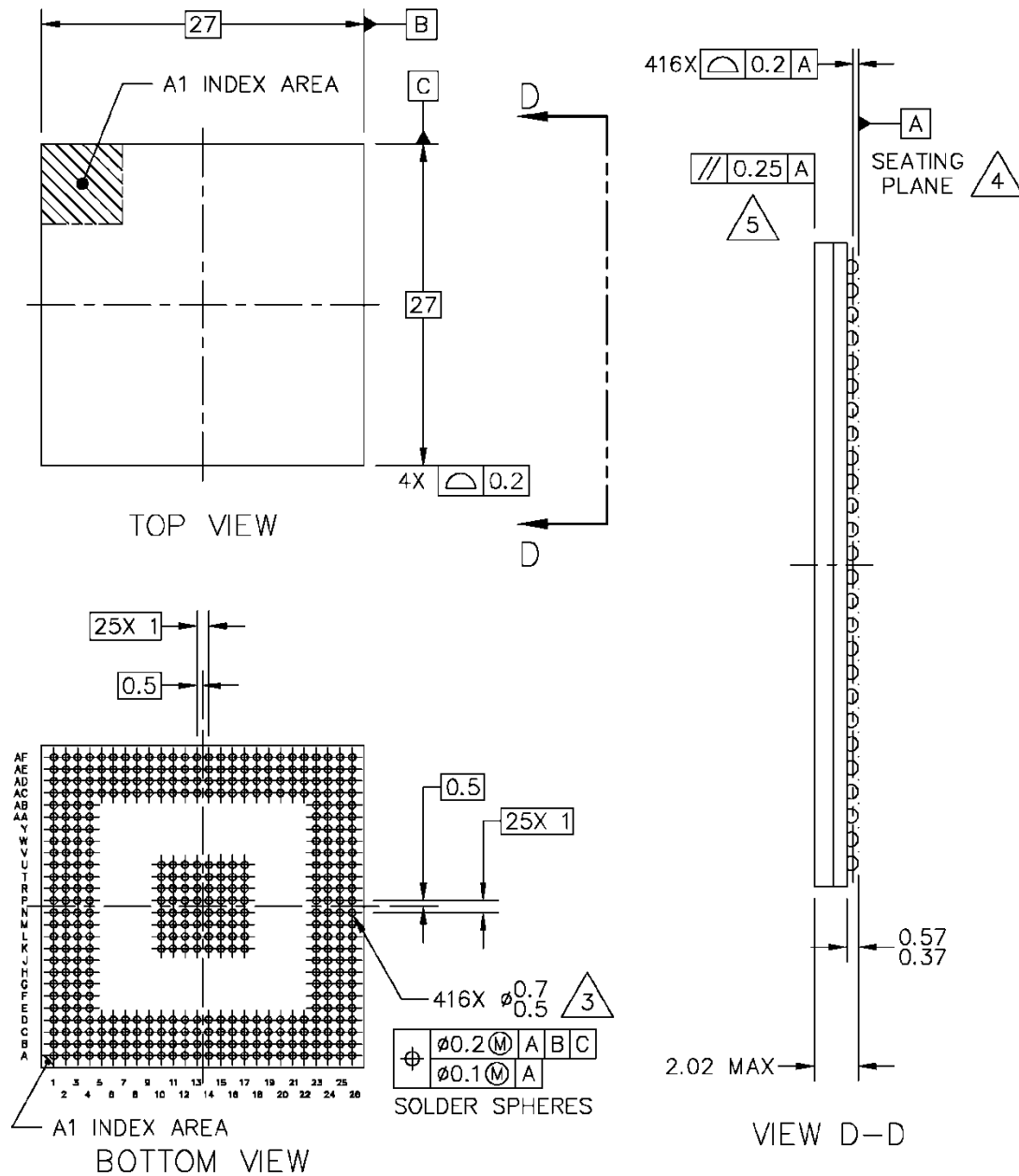


Figure 2. 416 TEPBGA (production) package mechanical drawing(Sheet 1 of 2)

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.

2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.

3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.

4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

6. DELETED IN REV O.

**Figure 2. 416 TEPBGA (production) package mechanical drawing(Sheet 2 of 2)**

## 4.2 216 HQFP (production) case drawing

### 1. Outline Drawing

Unit:mm

Package Code : HQFP216-P-2424

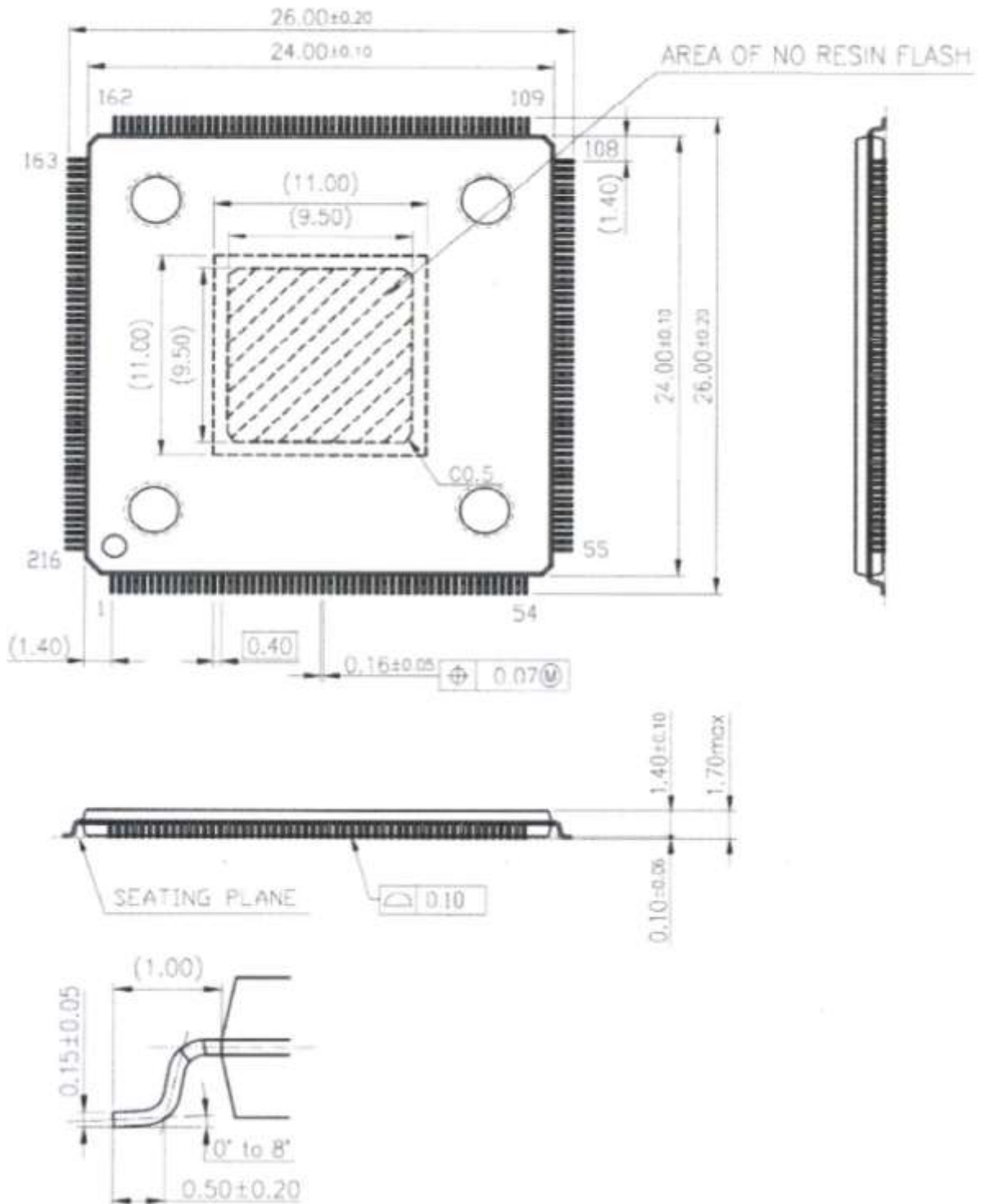


Figure 3. 216 HQFP (production) package mechanical drawing

## 5 Document revision history

| Revision | Date      | Description of changes                                                                            |
|----------|-----------|---------------------------------------------------------------------------------------------------|
| 1.0      | 2023/6/5  | Initial release                                                                                   |
| 1.1      | 2023/6/9  | Update CCFC3007PT pinmux and pinout.xlsx                                                          |
| 1.2      | 2023/6/16 | Update CCFC3007PT pinmux and pinout.xlsx                                                          |
| 1.3      | 2023/7/27 | Change name from CCFC3008PT200 to CCFC3007PT                                                      |
| 1.4      | 2023/8/8  | Modify CCFC3007PT family comparison Table<br>Table 4 Device operating conditions Min Value modify |